

Tuesday, November 8

Room B (Suzaku 2, 2F)

13:10-17:05 MNC 2016 Technical Seminar in Japanese

Room P (Heian 1, 2F)

17:25-19:25 Get Together Party**Wednesday, November 9****9P-1: Plenary Session**

Chairs: T. Tsuchiya (Kyoto Univ.) and T. Sato (Toshiba)

9P-1-0 9:30-9:50

Opening Remarks: H. Kotera (Kyoto Univ.)

Award Presentation: T. Tsuchiya (Kyoto Univ.) and H. Kotera (Kyoto Univ.), MNC 2015 Outstanding Paper, Most Impressive Presentation, Most Impressive Poster and Young Author's Award

Announcement from Committee: M. Suzuki (Kyoto Univ.)

9P-1-1 9:50-10:30

2D Crystals for Smart Life (Plenary)

K. Banerjee, UCSB, USA

Room P (Heian 1,2,3, 2F)

Coffee Break**9P-1-2 10:50-11:30**

New Device Application of Organic Semiconductors (Plenary)

S. Lee, Samsung Electronics, Korea

9P-1-3 11:30-12:10

Design Technology CoOptimization, The Key to Unlocking New Scaling Pathways (Plenary)

L. Liebmann, GLOBALFOUNDRIES, USA

Lunch

Room A (Heian 4, 2F)

Room B (Suzaku 2, 2F)

Room C (Suzaku 1, 2F)

Room D (Daigo, 2F)

9A-2: Nanocarbon Properties I

K. Matsuda (Kyoto Univ.)

R. Negishi (Osaka Univ.)

9B-2: Organic Nanomaterials

S. Takami (Tohoku Univ.)

H. Kasai (Tohoku Univ.)

9C-2: NanoTool I

R. Kometani (Univ. of Tokyo)

O. Kubo (Osaka Univ.)

9D-2: Symp. D: Innovation from Open Facilities I

H. Arimoto (AIST)

C. Gorecki (FEMTO-ST)

9A-2-1**13:30**

hBN-encapsulated Transition Metal Dichalcogenide van der Waals Heterostructures: Fabrication and Optical Properties

M. Okada 1, Y. Kureishi 1, K. Watanabe 2, T. Taniguchi 2, H. Shinohara 1 and R. Kitaura 1, 1 Nagoya Univ. and 2 NIMS, Japan

9B-2-1**13:30**

Protein Engineering for Interface Design on Inorganic Nanomaterials (Invited)

M. Umetsu, Tohoku Univ., Japan

9C-2-1**13:30**

Nanoscale Imaging and Fabrication by Focused Ion Beam System Equipped with Gas Field Ion Source (Invited)

T. Kozakai, Hitachi High-Tech Science, Japan

9D-2-1**13:30**

Overview of the Renatech Network of French Academic Clean-Rooms (Invited)

M.de Labacherie, I. Sagnes and C. Boisard, CNRS, France

9A-2-2**13:50**

Valley Relaxation in Transition Metal Dichalcogenide Monolayers

S. Konabe, Tokyo Univ. of Sci., Japan

9B-2-2**14:00**

Radial Mechanical Property of a Crossover Density-Varied DNA Nanotube

Z. Ma 1, S. Park1, N. Yamashita 1, K. Kawai 2, D.N. Kim 3, Y. Hirai 1, T. Tsuchiya 1 and O. Tabata 1,4, 1 Kyoto Univ., 2 Osaka Univ., Japan 3 Seoul Natl. Univ., Korea and 3 Albert-Ludwigs-Univ., Germany

9C-2-2**14:00**Ion Scattering Spectroscopy Study of ErSi₂ Nanowires Formed on Si(001)

K. Takahashi, O. Kubo, H. Kagitani, S. Osaka, H. Tabata and M. Katayama, Osaka Univ., Japan

9D-2-2**14:00**

Plasmon-Induced Photoenergy Conversion Systems Using Nano-Engineered Gold Particles (Invited)

H. Misawa 1,2, 1 Hokkaido Univ., Japan and 2 Natl. Chiao Tung Univ., Taiwan

9A-2-3**14:10**Ambipolar Transistors Based on Random Networks of WS₂ Nanotubes

M. Sugahara 1, H. Kawai 1, Y. Yomogida 1, Y. Maniwa 1, S. Okada 2 and K. Yanagi 1, 1 Tokyo Metropolitan Univ. and 2 Univ. of Tsukuba, Japan

9B-2-3**14:20**

Hyaluronic Acid-Activatable Nanoparticles for Targeted Prostate Cancer

Y.H. Lin 1, J.H. Lin 2, W.Y. Hua 3 and J.N. Li 1, 1 China Medical Univ., 2 Bio-medical Carbon Technol. and 3 Hung-Kuang Univ., Taiwan

9C-2-3**14:20**

Intramolecular Structure Imaging of Endohedral Metallofullerenes Using Frequency-Modulation Atomic Force Microscopy at Room Temperature

T. Yamashita, A. Noda, K. Kobayashi and H. Yamada, Kyoto Univ., Japan

9D-2-3**14:30**

Fabrication of High Sensitive Magnetic Field Sensor with Amorphous Wire and Fine Pitch Coils

T. Kato 1, S. Iwata 1 and Y. Honkura 2, 1 Nagoya Univ. and 2 Magnedesign, Japan

9A-2-4**14:30**

Opening a Gap in Graphene Encapsulated with hBN

H. Tomori 1,2, K. Nakamura 1, N. Hoshi 1, Y. Ootsuka 1, K. Watanabe 3, T. Taniguchi 3 and A. Kanda 1, 1 Univ. of Tsukuba, 2 JST-PRESTO and 3 NIMS, Japan

9B-2-4**14:40**

ASF-Coating PEI Nanoparticles with Layer Structure for Improved Gene Delivery

Y. Liu, P. Wang, Y. Zhang and M.Z. Li, Soochow Univ., China

9C-2-4**14:40**

Visualizing Three-Dimensional Adsorption Structures of Lubricant Molecules on a Hard Disk by Frequency Modulation Atomic Force Microscopy

K. Miyazawa 1, N. Nakajima 1, M. Toyoda 1, R. Sagata 2, T. Shimizu 2 and T. Fukuma, 1 Kanazawa Univ., 2 MORESCO and 3 ACT-C, Japan

9D-2-4**14:50**

Tensile Test of a Silicon Microstructure Fully Coated with Submicrometer-Thick DLC Film Using PECVD Method

W. Zhang, A. Uesugi, Y. Hirai, T. Tsuchiya and O. Tabata, Kyoto Univ., Japan

9A-2-5 15:10 Coexistence of Dirac Cones and Kagome Flat Bands in Porous Graphene M. Maruyama 1, N.T. Cuong 2 and S. Okada 1, 1 Univ. of Tsukuba and 2 NIMS, Japan	9B-2-5 15:00 Improvement of Ionic Liquids Wettability on Oxide Substrates and in Situ High-Speed Ellipsometry Diagnosis of IL Nano Thin Film Deposition K. Toyabe, S. Maruyama and Y. Matsumoto, Tohoku Univ., Japan	9C-2-5 15:00 Fluorescence Over-Recovery in Transient Response of Bacteriophage T4 DNA with YOYO-1 Electrical Stimulation of Virtual Electrode T. Hoshino and K. Mabuchi, Univ. of Tokyo, Japan	
9A-2: Author's Interview: 17:05-17:15	9B-2: Author's Interview: 15:20-15:30	9C-2: Author's Interview: 16:55-17:05	9D-2: Author's Interview: 16:55-17:05
Room P (Heian 1,2,3, 2F)			
Coffee Break			
Room A (Heian 4, 2F)	Room B (Suzaku 2, 2F)	Room C (Suzaku 1, 2F)	Room D (Daigo, 2F)
9A-3: Nanocarbon Growth M. Katagiri (Toshiba) M. Takamura (NTT)	9B-3: Electron and Ion Beam Technologies H. Yamashita (NuflareTechnol.) J. Yamamoto (Hitachi)	9C-3: NanoTool II R. Kometani (Univ. of Tokyo) T. Hoshino (Univ. of Tokyo)	9D-2: Symp. D: Innovation from Open Facilities II H. Arimoto (AIST) M. de Labacherie (Univ. of FrancheComte)
9A-3-1 15:25 Oxidative Decomposition of Carbon Nanotubes and Extraction of Encapsulated Materials H. Omachi, M. Yamagishi, M. Kato, R. Kitaura and H. Shinohara, Nagoya Univ., Japan	9B-3-1 15:35 An Application of 2-Dimensional Emitter Source for Multiple Electron Beam System (Invited) H.S. Kim, Y.B. Lee, S.W. Choi, H.W. Kim, D.-W. Kim, S.J. Ahn, T.S. Oh and Y.-H. Song, Sun Moon Univ., Korea	9C-3-1 15:35 Detection of Charge State of Single Molecules Using A GaAs-Based Nanowire Enhanced by Metal-Molecule Capacitive Coupling S. Okamoto, M. Sato, K. Sasaki and S. Kasai, Hokkaido Univ., Japan	9D-3-1 15:25 Vertical Comb-Drive Microscanner with 4x4 Array of Micromirrors for Phase-Shifting Mirau Micro-Interferometry (Invited) C. Gorecki, FEMTO-ST, France
9A-3-2 15:45 Synthesis of Multi-Layer h-BN Dependent on Catalyst Thickness by Chemical Vapor Deposition D. Kondo 1,2, K. Hayashi 1,2, M. Kataoka 1, T. Iwai 1 and S. Sato 1,2, 1 Fujitsu Labs. and 2 Fujitsu, Japan	9B-3-2 16:05 Effect of Tertiary Electrons in Single Event Time-of-Flight Rutherford Backscattering Spectrometry S. Abo 1, A. Seidl 2, F. Wakaya 1, M. Abe 1 and M. Takai 1, 1 Osaka Univ., Japan and 2 Magdeburg-stendal Univ. of Applied Sci., Germany	9C-3-2 15:55 Geometry Dependence of Temperature Coefficient of Resonant Frequency for Resonant Thermal Sensors N. Inomata and T. Ono, Tohoku Univ., Japan	9D-3-2 15:55 Examples of CMOS-MEMS Realizations within a France-Japan Collaboration (Invited) M. Denoual 1, E. Lebrasseur 2 and Y. Mita 2, 1 Univ. of Normandie, France and 2 Univ. of Tokyo, Japan
9A-3-3 16:05 Room Temperature Synthesis of Two-Dimensional Boron Sheets H. Nishino 1, T. Fujimori 1, A. Fujino 1, T. Fujita 2, N. Umezawa 3, S. Okada 1, E. Nishibori 1, S. Ito 1, J. Nakamura 1, H. Hosono 4 and T. Kondo 1,4, 1 Univ. of Tsukuba, 2 Tohoku Univ., 3 NIMS and 4 Tokyo Inst. of Technol., Japan	9B-3-3 16:25 Characteristics of Krypton Ion Emission from a Gas Field Ionization Source with a Single Atom Tip H. Shichi, S. Matsubara and T. Hashizume, Hitachi, Japan	9C-3-3 16:15 Mechanical Characterization of VLS-Grown Core-Shell SiC Nanowires for Nanomechanical Sensors S. Nakata 1, K. Sugano 1, F. Rossi 2, G. Salyati 2, A. Lugstein 3 and Y. Isono 1, 1 Kobe Univ., Japan, 2 IMEM-CNR Inst., Italy and 3 Vienna Univ. of Technol., Austria	9D-3-3 16:25 Three-Axis Angular Rate Sensor by Sputtered Lead-Free KNN Piezoelectric Films F. Horikiri, K. Watanabe and K. Shibata, Sciocs, Japan
9A-3-4 16:25 Influence of Copper Crystallographic Orientation on Growth and Etching of Graphene K.P. Sharma, G. Kalita and M. Tanemura, Nagoya Inst. of Technol., Japan	9B-3-4 16:45 Electron Beam Sources Using Semiconductor Photocathodes for Single-Shot Imaging Electron Microscope T. Nishitani, Y. Honda, D. Sato, M. Tabuchi and H. Amano, Nagoya Univ., Japan	9C-3-4 16:35 Characterization Method of Relative Raman Enhancement for Surface Enhanced Raman Spectroscopy Using Gold Nanoparticle Dimer Array K. Ikegami, K. Sugano and Y. Isono, Kobe Univ., Japan	9D-3-4 16:45 MEMS-Based Near Infrared Region (NIR) Spectrometer with Silicon Prism Structure S.H. Son 1, S.J. Bang 1, S.Y. Kwon 1, D.G. Jung 1, W.I. Jang 2 and S.H. Kong 1, 1 Kyungpook Natl. Univ. and 2 ETRI, Korea
9A-3-5 16:45 Direct Fabrication of Graphene on Atomically Flat Diamond (111) Surface by a Nickel Catalyst S. Kanada 1, Y. Katagiri 1, M. Nagai 1, S. Ito 1, T. Matsumoto, T. Ogura 2, D. Takeuchi 2, S. Yamasaki 2 N. Tokuda 1 and T. Inokuma 1, 1 Kanazawa Univ. and 2 AIST, Japan	9B-3-5 17:05 Scanning Electron Microscope Line-Profile Analysis of Less-Than-10-nm Patterns M. Hatano 1, Y. Nakayama 1, S. Hotta 1, Y. Momono 2, and Z. Wang 2, 1 Hitachi and 2 Hitachi High-Technologies, Japan		
9A-3: Author's Interview: 17:05-17:15	9B-3: Author's Interview: 17:25-17:35	9C-3: Author's Interview: 16:55-17:05	9D-3: Author's Interview: 17:05-17:15
Room A (Heian 4, 2F) and Room P (Heian 1,2,3, 2F)			
17:35-19:00 Room A 17:35-17:40 17:40-17:45 17:45-17:50 17:50-17:55 17:55-18:00	Happy Hour (Sponsored by Technical Exhibitors) Happy Hour Remark JPK Instruments Photo electron Soul Inc. AGADVANTEST GenISys	18:00-18:05 18:05-18:10 18:10-18:15	Nanotechnology Platform Japan Quantum Design Japan, Inc. & Swiss Litho AG Korean Physical Society / Organizing Committee of the MNC 2017

Thursday, November 10

Room A (Heian 4, 2F)	Room B (Suzaku 2, 2F)	Room C (Suzaku 1, 2F)	Room D (Daigo, 2F)
10A-4: Symp. C: Nanosensors and Their Promises for IoT Society I T. Yanagida (Kyushu Univ.) Y. Hotta (Univ. of Hyogo)	10B-4: Nanocarbon Properties II G. Kalita (Nagoya Inst. of Technol.) S. Konabe (Tokyo Univ. of Sci.)	10C-4: Nanofabrication I K. Makihara (Nagoya Univ.) Y. Liu (AIST)	10D-4: Microsystem Technology & MEMS I T. Namazu (Aichi Inst. of Technol.) S. Nagasawa (Shibaura Inst. of Technol.)
10A-4-1 9:00 Ultra-Low Energy Nano-Scaled Sensors for IoT Systems (Invited) K. Uchida, Keio Univ., Japan	10B-4-1 9:00 Strain-Induced Semiconducting Electron Transport in Graphene Field Effect Device S. Higuchi 1, R. Hiraide 1, T. Kichikawa 1, Y. Ootuka 1, H. Tomori 1,2 and A. Kanda 1, 1 Univ. of Tsukuba and 2 JST-PRESTO, Japan	10C-4-1 9:00 Formation and Characterization of Elemental 2D Materials Beyond Graphene (Invited) Y. Yamada-Takamura, JAIST, Japan	10D-4-1 9:00 Application on SiC Power Semiconductors to Environmentally Friendly Vehicles (Invited) T. Nishiwaki, T. Koyama and T. Ito, Toyota Motor, Japan
10A-4-2 9:30 Integrated Circuits for Big Data and Small Sensors (Invited) T. Kuroda, Keio Univ., Japan	10B-4-2 9:20 Electronic Properties of PCBM under an External Electric Field S. Furutani and S. Okada, Univ. of Tsukuba, Japan	10C-4-2 9:30 Experimental Study of Solid Source Diffusion by Spin on Dopants and Its Application for Minimal SOI-CMOS Fabrication Y.X. Liu, K. Koga, S. Khumpuang, M. Nagano, T. Matsukawa and S. Hara, AIST, Japan	10D-4-2 9:30 A Fully Printed Cantilever for Additive Manufacturing of Force Gauge S. Kanazawa, Y. Kusaka, N. Yamamoto and H. Ushijima, AIST, Japan
10A-4-3 10:00 Macro-Scale, Multi-Sensing Flexible Devices for Human Interactive Applications (Invited) K. Takei, Osaka Pref. Univ., Japan	10B-4-3 9:40 Electrical Tunable Localized States in Sub-Band of Bilayer Graphene Nanoribbon J. Sun 1,2, M. Muruganathan 2, K. Ishibashi 1 and H. Mizuta 2,3, 1 RIKEN, 2 JAIST, Japan and 3 Univ. of Southampton, UK	10C-4-3 9:50 Low Temperature Formation of Crystalline Si:H/Ge:H Heterostructures by Plasma Enhanced CVD in Combination with Ni-NDs Seeding Nucleation Y. Lu, K. Makihara, D. Takeuchi, M. Ikeda, A. Ohta and S. Miyazaki, Nagoya Univ., Japan	10D-4-3 9:50 Microfabricated Emitter Arrays for an Ionic Liquid Electro spray Thruster K. Nakagawa 1, T. Tsuchiya 2 and Y. Takao 1, 1 Yokohama Natl. Univ., 2 Kyoto Univ., Japan
	10B-4-4 10:00 Interaction of Few Layer MoS ₂ and Adsorbed Dopamine T.T. Nguyen 1,2, T. Komeda 1 and A. Ando 2, 1 Tohoku Univ. and 2 AIST, Japan	10C-4-4 10:10 Fabrication of Sub-20 nm Metal Electrodes on 2D Materials without a Charged Particle Beam F. Holzner 1, H. Wolf 2, C. Rawlings 2, U. Duerig 2, A.W. Knoll 2, M. Spieser 1, S. Bonanni 1 and P. Paul 1, 1 SwissLight and 2 IBM Res., Switzerland	10D-4-4 10:10 SMA Rapid Cooling System Using Liquid Transport by Capillary Phenomenon I. Matsui and S. Nakagawa, Shibaura Inst. of Technol., Japan
10A-4: Author's Interview: 11:45-11:55	10B-4: Author's Interview: 12:25-12:35	10C-4: Author's Interview: 10:30-10:40	10D-4: Author's Interview: 12:05-12:15
Room P (Heian 1,2,3, 2F)			
Coffee Break			
Room A (Heian 4, 2F)	Room B (Suzaku 2, 2F)	Room C (Suzaku 1, 2F)	Room D (Daigo, 2F)
10A-5: Symp. C: Nanosensors and Their Promises for IoT Society II T. Yanagida (Kyushu Univ.) K. Uchida (Keio Univ.)	10B-5: Nanocarbon Application A. Ando (AIST) K. Yanagi (Tokyo Metropolitan Univ.)	10C-5: Nanofabrication II K. Takase (Nihon Univ.) H. Tanaka (Kyushu Inst. of Technol.)	10D-5: Microsystem Technology & MEMS II R. Takigawa (Kyushu Univ.) Y. Tomizawa (Toshiba)
10A-5-1 10:45 On-Chip FRET Biosensor Build on Graphene-Biomolecular-Interface (Invited) Y. Ueno 1 and K. Furukawa 1,2, 1 NTT and 2 Meisei Univ., Japan	10B-5-1 10:35 Dry Manufacturing of Carbon Nanotube Thin Films for Flexible Electronics Applications (Invited) E.I. Kauppinen, Aalto Univ. School of Science, Finland	10C-5-1 10:55 Controlling Flake Size and Shape of MoS ₂ Monolayers Grown by Chemical Vapor Deposition (Invited) A. Özden, F. Ay, C. Sevik and N.K. Pergöç, Anadolu Univ., Turkey	10D-5-1 10:45 Young's Modulus Evaluation of Electroplated Ti/Au Structures for MEMS Devices D. Yamane 1,2, T. Konishi 3, T. Safu 3, H. Nakajima 1,2, M. Teranishi 1,2, C.-Y. Chen 1,2, T.-F.M. Chang 1,2, M. Sone 1,2, H. Toshiyoshi 2,3, K. Masu 1,2 and K. Machida 2,3, 1 Tokyo Inst. of Technol., 2 JST-CREST, 3 NTT-AT and 3 Univ. of Tokyo, Japan
10A-5-2 11:15 High-Resolution 2D/3D Printing Techniques for Wearable Electronics (Invited) J.-U. Park, UNIST, Korea	10B-5-2 11:05 Photoinduced Force on Polystyrene Microsphere Measured by Carbon Nanotube Mechanical Resonator M. Yasuda, K. Takei, T. Arie and S. Akita, Osaka Pref. Univ., Japan	10C-5-2 11:25 Extraction of Bandgap in Graphene Nanoribbon by Adsorption of Molecular Nanoparticle R.R. Pandey, P. Liu and H. Tanaka, Kyushu Inst. of Technol., Japan	10D-5-2 11:05 Electroless Ni Plating of Seed Film of Electrophoresis of Ag Nanoparticles K. Nitta 1, R. Takigawa 1, A. Ikeda 1, M. Kumazawa 2, T. Hirai 2, M. Komatsu 2 and T. Asano 1, 1 Kyushu Univ. and 2 JGC Catalysts and Chemicals, Japan

	<p>10B-5-3 11:25 Intercalation Doping of MoCl₅ into Low-Temperature-Grown Multilayer Graphene M. Katagiri 1, H. Miyazaki 1, R. Matsumoto 2, T. Matsumoto 3, R. Ifuku 3, T. Sakai 1 and A. Kajita 1, 1 Toshiba, 2 Tokyo Polytechnic Univ. and 3 Tokyo Electron, Japan</p>	<p>10C-5-3 11:45 Rapid Visualization of Latent Fingerprints Using Gold Seed Enhancement C.-C. Yu 1, F.-Y. Cheng 2 and C.-H. Su 1, 1 Natl. Yang Ming Univ. and 2 Natl. Cheng Kung Univ. and Hospital, Taiwan</p>	<p>10D-5-3 11:25 Mechanical Properties Characterization and Fabrication Damage Investigation of Silicon Nanowires Based on Four-Different Sample Preparation Techniques G. Ina 1, T. Fujii 2, T. Kozeki 1, S. Inoue 1 and T. Namazu 3, 1 Univ. of Hyogo, 2 Akita Pref. Univ. and 3 Aichi Inst. of Technol., Japan</p>
	<p>10B-5-4 11:45 Diffusion of Li Atom from a Solvated State to Interlayer of Graphite through Carbonylic Edge Termination for Fast Charge/Discharge of Li Ion Battery: First-Principles Calculations T. Kawai 1,2, S. Okada 2 and M. Otani 3, 1 NEC, 2 Univ. of Tsukuba and 3 AIST, Japan</p>	<p>10C-5-4 12:05 Dopant Distribution in Nickelated Si Nanowire Surrounded by SiO₂ Film Characterized by Laser-Assisted Atom Probe Tomography S. Hashimoto 1, S. Asada 1, T. Xu 1, S. Oda 1, T. Matsukawa 2 and T. Watanabe 1, 1 Waseda Univ. and 2 AIST, Japan</p>	<p>10D-5-4 11:45 Reduction of Thermal Resistance in Al/Ni-reactively-bonded Solder Joints by Thickening the Outermost Layers S. Kanetsuki 1,2, K. Kuwahara 3, S. Egawa 3, S. Miyake 4 and T. Namazu 2, 1 Kobelco Res. Inst., 2 Aichi Inst. of Technol., 3 Univ. of Hyogo and 4 Kobe City College of Technol., Japan</p>
	<p>10B-5-5 12:05 Modeling and Technology Platform for Analog High Frequency Carbon Nanotube Transistors (Invited) S. Hermann 1,2,3, M. Claus 3, S.E. Schulz 1,2,3, M. Schröter 3,4, 1 TU Chemnitz, 2 ENAS, 3 TU Dresden, Germany and 4 UC San Diego, USA</p>		
	<p>10B-5: Author's Interview: 12:35-12:45</p>	<p>10C-5: Author's Interview: 12:25-12:35</p>	<p>10D-5: Author's Interview: 12:05-12:15</p>
Lunch			
Room A (Heian 4, 2F)	Room B (Suzaku 2, 2F)	Room C (Suzaku 1, 2F)	Room D (Daigo, 2F)
<p>10A-6: Symp. B: Forefront of Graphene & Related 2D Materials D. Kondo (Fujitsu Labs.) K. Maehashi (Tokyo Univ. of Agriculture and Technol.)</p>	<p>10B-6: Inorganic Nanomaterials I M. Osada (NIMS) M. Suzuki (AIST)</p>	<p>10C-6: Nanofabrication III R. Hasunuma (Tsukuba Univ.) A. Kohno (Fukuoka Univ.)</p>	<p>10D-6: Nanoimprint, Nanoprint and Rising Lithography A. Yokoo (NTT) H. Lee (Korea Univ.)</p>
<p>10A-6-1 14:10 Diamane and Diamond (Invited) (Invited) R.S. Ruoff, UNIST, Korea</p>	<p>10B-6-1 14:10 Indium Oxide Nanowires as Efficient Antireflection Layers in Multicrystalline Silicon Solar Cells T.-I. Chin 1, Y. -C. Wang 1, C.-W. Kuo 2, T.-M. Kuan 2, C.-Y. Yu 2 and I.-C. Chen 1, 1 Natl. Central Univ. and 2 TSEC, Taiwan</p>	<p>10C-6-1 14:10 III-V Nanowires for Solar Cell and Energy Applications (Invited) H.H. Tan, Australian Natl. Univ., Australia</p>	<p>10D-6-1 13:40 Enhanced Light Extraction Efficiency in Organic Light Emitting Diode Using NIL (Invited) Y.D. Kim, H.-J. Choi, Y.H. Sung and H. Lee, Korea Univ., Korea</p>
<p>10A-6-2 14:40 Controlling Charge Transport, Spin Transport and Superconductivity in a Two-Dimensional Materials by the Electric Field Effect (Invited) B. Özyilmaz, National Univ. of Singapore, Singapore</p>	<p>10B-6-2 14:30 Crystallographic Polarity Effect of ZnO on Electronic State of Pentacene/ZnO Hetero Structure T. Nagata 1, T. Nakamura 1,2, R. Hayakawa 1, T. Yoshimura 2, S. Oh 1, N. Hiroshiba 1,3, T. Chikyow 1, N. Fujimura 2 and Y. Wakayama 1, 1 NIMS, 2 Osaka Pref. Univ. and 3 Tohoku Univ., Japan</p>	<p>10C-6-2 14:40 Evaluation of Titanium-Assisted Chemical Vapor Etching of Silicon Dioxide R. Kometani, T. Murakami and E. Maeda, Univ. of Tokyo, Japan</p>	<p>10D-6-2 14:10 Direct Imprinting of Liquid Silicon for Si Fine Patterns K. Yamazaki, T. Matsuda and T. Shimoda, JAIST, Japan</p>
		<p>10C-6-3 15:00 Heterogeneous Integration of Vertical In_xGa_{1-x}As Nanowires on Ge(111) Substrates by Selective-Area MOVPE A. Yoshida 1, F. Ishizaka 1, K. Tomioka 1,2 and J. Motohisa 1, 1 Hokkaido Univ. and 2 JST-PRESTO, Japan</p>	<p>10D-6-3 14:30 Novel Computational Study on Sub-10nm UV Curing Characteristic in Nanoimprint Lithography by Stochastic Approach N. Koyama, M. Shirai, H. Kawata, Y. Hirai and M. Yasuda, Osaka Pref. Univ., Japan</p>
<p>10A-6-3 15:10 Fundamental Properties and Applications of Two-Dimensional Materials (Invited) T. Kondo 1,2, 1 Univ. of Tsukuba and 2 Tokyo Inst. of Technol., Japan</p>	<p>10B-6-3 14:50 Facile Synthesis of Mesoporous ZnCo₂O₄ Nanoparticles Using Polyvinyl Pyrrolidone as Growth Modifier for High-Performance Supercapacitor G.M. Tomboc, H.S. Jadhav and H. Kim, Myongji Univ., Korea</p>	<p>10C-6-4 15:20 Nanofabrication of Magnetic Tunnel Junctions toward Sub-20 nm Φ for Embedded Cache Memory in High Performance CPUs T. Sugii, H. Noshiro, Y. Yamazaki, C. Yoshida and Y. Iba, Fujitsu, Japan</p>	<p>10D-6-4 14:50 High-resolution Embedded Printing Using Imprinted Microgrooves for Transparent Applications R. Hokai, K. Kurihara, N. Takada, S. Matsumoto and H. Hiroshima, AIST, Japan</p>

10A-6-4 15:40 Graphene for Field Emission Applications (<i>Invited</i>) W.I. Milne 1,3, C. Li 2, W. Lei 2, B. Wang 2, G. Duesberg 4, T. Hallam 4 and M.T. Cole 1, 1 Univ. of Cambridge, UK, 2 SEU, China, 3 Tokyo Inst. of Technol., Japan and 4 Trinity College Dublin, Ireland	10B-6-4 15:10 Superlattice Study of Lanthanum Cuprate Nanoparticles Synthesized via Sol-Gel Process under Air Pressure F. Budiman, Y. Horibe, Y. Fusao and H. Tanaka, Kyushu Inst. of Technol., Japan	10C-6-5 15:40 The Design of High Resolution Low Temperature Polycrystalline Silicon Optical Fingerprint Sensor with 100 Nanometer Thick Absorption Layer Y.-C. Wei, Y.-C. Li, I.-C. Lee and H.-C. Cheng, Natl. Chiao Tung Univ., Taiwan	10D-6-5 15:10 Viscoelasticity of a Photoresist Used for Nanoimprint Lithography Measured Under Confinement in Nanometer-Sized Gaps S. Ito 1, K. Takahashi 2, K. Fukuzawa 1 and H. Zhang 1, 1 Nagoya Univ. and 2 Toyohashi Univ. of Technol., Japan
	10B-6: Author's Interview: 15:30-15:40	10C-6: Author's Interview: 16:00-16:10	10D-6-6 15:30 Nanoimprint System Development and Status for High Volume Semiconductor Manufacturing (<i>Invited</i>) Y. Kondo 1, N. Nishimura 1, T. Takashima 1, T. Matsumoto 1, T. Hayashi 1, A. Kimura 1, K. Emoto 1, J. Choi 2 and P. Schumaker 2, 1 Canon, Japan and 2 Canon Nanotechnol., USA
Room P (Heian 1,2,3, 2F)			
Coffee Break			
Room P (Heian, 2F)			
10P-7: 16:10-18:10 POSTER SESSION I			
Electron and Ion Beam Technologies			
Chairperson: H. Yamashita (NuflareTechnol.)			
10P-7-1 Optimization of Gold Lamellae Nanostructures as Gas/Liquid Sensors Based on LSPRs S. Zhang, Y. Chen, B. Lu, J. Liu, J. Shao and C. Xu, Fudan Univ., China	10P-7-2 Progress and Process Improvements for Multiple E-Beam Direct Write I. Servin 1, M.-L. Pouteau 2, P. Essomba 1, J. Pradelles 1, L. Lattard 1, P. Brandt 2 and M. Wieland 2, 1 CEA-LETI, France and 2 MAPPER Lithography, The Netherlands	10P-7-3 Measurement of Fogging Electron Current for Various Beam Energies at Acceleration Bias in Scanning Electron Microscope Y. Hagiwara, T. Noda and M. Kotera, Osaka Inst. of Technol., Japan	10P-7-4 Simulation of Charging Process of PMMA Film on Si Substrate under Electron Beam Irradiation A. Fukuzawa and M. Kotera, Osaka Inst. of Technol., Japan
10P-7-5 Surface Potential Distribution of a Resist Film Irradiated by Electron Beam under Acceleration Bias M. Tokai, T. Kawamoto and M. Kotera, Osaka Inst of Technol., Japan	10P-7-6 Formation of Nano-bump Structures on Si(100) Surfaces by Low-Energy Ga Ion Irradiation S. Suzue, Y. Matsui and J. Yanagisawa, Univ. of Shiga, Japan	10P-7-100L Measurement of Fogging Electron Current at a Specimen Surface in Scanning Electron Microscope N. Taku, Y. Hagiwara and M. Kotera, Osaka Inst. of Technol., Japan	10P-7-101L Development of a Simulation of Fogging Electron Trajectories in a Scanning Electron Microscope T. Nishino, K. Terada, Y. Hagiwara, T. Noda and M. Kotera, Osaka Inst. of Technol., Japan
10P-7-102L Radial Field Gun Designs for Focused Multi-Beam Electron Columns A. Khursheed and W.K. Ang, Natl. Univ. of Singapore, Singapore	10P-7-103L Early Stages of Development Process in Electron-Exposed Resists: A Molecular Dynamics Study S. Hitomi, H. Kawata, Y. Hirai and M. Yasuda, Osaka Pref. Univ., Japan		
Nanocarbons			
Chairperson: S. Okada (Univ. of Tsukuba)			
10P-7-7 Formation of Co Capped Carbon Nanotube in TEM M.S. Rosmi 1,2, Y. Yaakob 1,3, M. Ibrahim Araby 1, S. Sharma 1, M. Z. Mohd Yusop 4, G. Kalita 1, M. Kitazawa 5 and M. Tanemura 1, 1 Nagoya Inst. of Technol., Japan, 2 Univ. Pendidikan Sultan Idris, 3 Univ. Putra Malaysia, 4 Univ. Technol. Malaysia, Malays and 5 Olympus, Japan	10P-7-8 Electrochemical Study of Dopamine at Electrode Fabricated by Long-Length Carbon Nanotube Dispersed Solution Y. Inoue 1, H. Muguruma 1, H. Inoue 2 and T. Ohsawa 2, 1 Shibaura Inst. of Technol. and 2 Nippon Shizai, Japan	10P-7-9 Growth of Nitrogen-Doped Graphene Constructed Nanofibers on Nichrome Foil R. Vishwakarma, G. Kalita and M. Tanemura, Nagoya Inst. of Technol., Japan	10P-7-10 MoS ₂ Based Back-Gate FETs for Photodetectors A. Ando 1, D. Kondo 2 and S. Sato 2, 1 AIST and 2 Fujitsu Labs., Japan
10P-7-11 Thermal Response Evaluation of Carbon-Nanotube-Composite Paper for "Thermoelectric Power Generation Paper" K. Kawata and T. Oya, Yokohama Natl. Univ., Japan	10P-7-12 Effects of Pyrene Adsorption Density as an Anchor Molecules on Biosensor Response Using Reduced Graphene Oxide Thin Film Transistor R. Negishi, Y. Matsui and Y. Kobayashi, Osaka Univ., Japan	10P-7-13 Novel Tetracationic Ionic Liquids: Synthesis, Characterization, and Application as Carbonaceous Precursors A.H. Tamboli and H. Kim, Myongji Univ., Korea	10P-7-14 Superconducting Proximity Effect in Graphene/Layered Superconductor NbSe ₂ Interface K. Yarimizu 1, Y. Ootsuka 1, H. Tomori 1,2, K. Watanabe 3, T. Taniguchi 3, K. Ueno 4 and A. Kanda 1, 1 Univ. of Tsukuba, 2 JST-PRESTO, 3 NIMS and 4 Saitama Univ., Japan

10P-7-15 Large Scale Preparation of Macroscopic Graphene Fiber Based on Acidic Condition Z. Zhang, D. Zhang, H. Lin and Y. Chen, Soochow Univ., China	10P-7-16 Amperometric Biosensor with Single-Walled Carbon Nanotube and Flavin Adenine Dinucleotide-Dependent Glucose Dehydrogenase H. Hidaka 1, H. Muguruma 1, H. Iwasa 2, A. Hiratsuka 2 and H. Uzawa 2, 1 Shibaura Inst. of Technol. and 2 AIST, Japan	10P-7-17 Li Atom Adsorption on Graphene with Various Defects for Large-Capacity Li Ion Batteries: First-principles Calculations K. Shiota 1 and T. Kawai 1,2, 1 Univ. of Tsukuba and 2 NEC, Japan	10P-7-18 Numerical Simulation of High-Voltage Diamond Schottky Barrier Diodes D.-W. Kang 1, H.N. Chang 2 and M.-W. Ha 2, 1 Cheongju Univ. and 2 Myongji Univ., Korea
10P-7-19 Direct Deposition of Graphene on GaN by Thermal CVD at Low Temperatures K. Aida, T. Enomoto, H. Arai, K. Yokosawa and K. Ueno, Shibaura Inst. of Technol., Japan	10P-7-20 Electronic Structure of Bilayer Graphene with Defects under an External Electric Field K. Kishimoto and S. Okada, Univ. of Tsukuba, Japan	10P-7-104L Electrochemical Ion-Storage Behavior of Organic Molecules Confined in Single-Walled Carbon Nanotubes C. Li, Y. Sakamoto, Y. Ishii and S. Kawasaki, Nagoya Inst. of Technol., Japan	10P-7-105L Gas Response Characteristics of Graphene/MoS ₂ Heterojunction to NO ₂ H. Tabata, Y. Sato, O. Kubo and M. Katayama, Osaka Univ., Japan

Nanodevices

Chairperson: Y. Hotta (Univ. of Hyogo)

10P-7-21 Magneto-Optical Cavity Effect on Perpendicular Magnetic Multilayers for Hydrogen Gas Sensing Application H. Yamane 1, H. Yamasaki 2, K. Sumiyoshi 2 and K. Shigemura 2, 1 Akita Industrial Technol. Ctr. and 2 NLT Technol., Japan	10P-7-22 Effects of Post Metal Annealing Thermal Budget on Electrical Characteristics of HfO _x -Based RRAM Devices K.-C. Chuang, K.-Y. Lin, J.-D. Luo, C.-Y. Chu and H.-C. Cheng, Natl. Chiao Tung Univ., Taiwan	10P-7-23 Nanofabrication of Polarizers for InP Based InGaAs Sensor by Electron Beam Lithography X. Huang 1, J. Shao 1, R. Wang 2, T. Li 2, X. Shao 2, X. Li 2, H. Gong 1 and Y. Chen 1, 1 Fudan Univ. and 2 SITP, China	10P-7-24 p-Cu ₂ O/AlO _x /n-SiC/n-Si-Structured Nonvolatile pn Memory Diode with Low Switching Voltages M. Tsuchiya, T. Tsukamoto and Y. Suda, Tokyo Univ. of Agriculture and Technol., Japan
10P-7-25 Sodium Chloride Concentration Measurement with p-type Doping Nanowire Sensor C.-C. Hsu 1, Y.-T. Tsai 1, G.-W. Wu 1, C.-C. Wu 2 and C.-L. Dai 3, 1 Yuan Ze Univ., 2 Tamkang Univ. and 3 Natl. Chung Hsing Univ., Taiwan	10P-7-26 Acceptor Doping Effect on Rutile Type TiO ₂ /Ge Stack Structure by Combinatorial Synthesis Y. Suzuki 1,2, T. Nagata 2,3, Y. Yamashita 2, T. Nabatame 2, A. Ogura 1 and T. Chikyow 2, 1 Meiji Univ., 2 NIMS and 3 JST-PRESTO, Japan	10P-7-27 Effects of Heater Power and Gas Medium on the Sensitivity of a CNT Yarn Inclinator D.-W. Jung 1,3, Y.-H. Hwang 1, J.G. Kim 1, S.Y. Kwon 2, D.G. Jung 2, S.H. Kong 2 and G.S. Lee 3, 1 KITECH, 2 Kyungpook Natl. Univ., Korea and 3 Univ. of Texas, USA	10P-7-28 Study of Single-Electron Information-Processing Circuit Mimicking Foraging Behavior of Honeybee Swarm T. Tanabe and T. Oya, Yokohama Natl. Univ., Japan
10P-7-29 Design of Slime-Mold-Inspired Multi-Layered Single-Electron-Circuit K. Satomi and T. Oya, Yokohama Natl. Univ., Japan	10P-7-30 Fabrication of Single-Electron Transistor Made of Fe-Dot Film and Its Characteristics S. Honjo, T. Uchida, A. Tsurumaki-Fukuchi, M. Arita and Y. Takahashi, Hokkaido Univ., Japan	10P-7-31 Temperature Dependence of the Biaxial Tensile Strain in Suspended Ge Cross-Shaped Microstructures S. Ishida 1, S. Kato 1, K. Oda 2, S. Iwamoto 1 and Y. Arakawa 1, 1 Univ. of Tokyo and 2 Hitachi, Japan	10P-7-106L Si ₃ N ₄ -Based RRAM with Flexibility of Physical Design S. Kim 1, S. Jung 1, M.-H. Kim 1, T. Kim 2, S. Bang 2, S. Cho 2, and B.-G. Park 1, 1 Seoul Natl. Univ. and 2 Gachon Univ., Korea
10P-7-107L The Study on the Application of Low-Temperature Polycrystalline-Silicon Thin-Film Transistors in Digital X-ray Image Sensors Y.-C. Wei 1, Y.-C. Li 1, I.-C. Lee 2 and H.-C. Cheng 1, 1 Natl. Chiao Tung Univ. and 2 ITRI, Taiwan	10P-7-108L Solution-Based Formation of High Quality Gate Dielectrics on Graphene Using Microwave-Assisted Annealing K.-S. Kim, G.-H. Park, H. Fukidome, T. Suemitsu, T. Otsuji and M. Suemitsu, Tohoku Univ., Japan	10P-7-109L Dimension Dependent Immunity of X-ray Irradiation on LTPS TFTs Y.-C. Wei 1, Y.-C. Li 1, I.-C. Lee 2 and H.-C. Cheng 1, 1 Natl. Chiao Tung Univ. and 2 ITRI, Taiwan	10P-7-110L Systematic Analysis of Passivation and Annealing Effects on Degradation of Electrical Performance of Black Phosphorus FETs M.-K. Song 1,2, A.-J. Cho 1,2, H.-J. Kim 1,2 and J.-Y. Kwon 1,2, 1 Yonsei Univ. and 2 Yonsei Inst. of Convergence Technol., Korea

Nanofabrication

Chairperson: K. Takase (Nihon Univ.)

10P-7-32 Fiber-based Micro Temperature Sensor by Using Three-Dimensional Photomask Y. Kim 1,2, Y. Zhang 1 and M. Hayase 2, 1 AIST and 2 Tokyo Univ. of Sci., Japan	10P-7-33 Single-cell Isolation of <i>S. Cerevisiae</i> Using Celluloid Microenclosure Array Formed by the SUMP Method A. Matsutani and A. Takada, Tokyo Inst. of Technol., Japan	10P-7-34 Formation of Au Nanoparticle Arrays on Hydrogel 2-D Patterns Based on Poly(Vinylpyrrolidone) S. Tsukuda 1,3, K. Okamoto 2,3, H. Yamamoto 3, T. Kozawa 3 and T. Omata 1, 1 Tohoku Univ., 2 Hokkaido Univ. and 3 Osaka Univ., Japan	10P-7-35 High Aspect Ratio GaN Nanorods Fabricated by Means of UV Photolithography and ICP Etching M. Ekielski 1, M. Wzorek 1, M.A. Borysiewicz 1, A. Domanowska 2, T. Wojtowicz 1, A. Piotrowska 1 and E. Kamińska 1, 1 Al. Lotników and 2 Silesian University of Technol., Poland
10P-7-36 Fabrication of Less Reflective Nanowhisker on Textured Substrates C.W. Lin and J.W. Wang, Tatung Univ., Taiwan	10P-7-37 Graphene Oxide-assisted Preparation of Polyvinyl Alcohol (PVA) Hybrid Nanofiber by Electrospinning for Biomedical Application Z.-C. Chen and T.-L. Chang, Natl. Taiwan Normal Univ., Taiwan	10P-7-38 A Novel Approach for Reducing Line Edge Roughness by a Thermal Radiation Induced Local Reflow Process C. Xu, S. Zhang and Y. Chen, Fudan Univ., China	10P-7-39 Nanofabrication of Ultra-Tall Silicon Nano-Pillars by Inductively Coupled Plasma Etch with Hydrogen Sulfide as Etching Mask X. Li, C. Shuo, J. Shao, L. Bingrui and Y. Chen, Fudan Univ., China

10P-7-40 Cell Adhesion and Proliferation on Polytetrafluoroethylene with Plasma-metal and Plasma-Metal-Carbon Interfaces A. Reznickova, K. Kolarova, Z. Smejkalova, O. Kvittek and V. Svorcik, VSCHT, Czech	10P-7-41 Precise Tuning of Surface Plasmon Resonance Wavelength of Anisotropic Silver Nanoprisms by Removing Surface Protective Agent S. Igari, R. Miyasaka, S. Jun, K. Uchida, K. Sugawa, K. Takase and J. Otsuki, Nihon Univ., Japan	10P-7-42 Gas Barrier Performances of ALD-Al ₂ O ₃ /ZnO Laminated Films H. Zama and K. Honda, ULVAC, Japan	10P-7-111L Fabrication of Silicon Nano-Wedge Structure by Anisotropic Chemical Etch Process Using TMAH Solutions M.-H. Kim 1, S. Jung 2 and B.-G. Park 1, 1 Seoul Natl. Univ. and 2 Samsung Electronics, Korea
--	---	--	---

Inorganic Nanomaterials

Chairperson:

10P-7-43 Withdrawn A Facile Synthesis of Silica-Coated FeCo Nanocubes K. Chokprasombat 1, S. Pinitsoontorn 2 and S. Maensiri 3, 1 Thaksin Univ., 2 Khon Kaen Univ. and 3 Suranaree Univ. of Technol., Thailand	10P-7-44 Physically-Synthesized Porous Gold Nanoparticles for Biological Applications J. Park 1,2, H. Kang 1, Y.H. Kim 1, S.-W. Lee 1, T.G. Lee 1 and J.-S. Wi 1, 1 KRISS and 2 Sungkyunkwan Univ., Korea	10P-7-45 Gas Sensor Applications of Zinc Oxide-Vanadium Oxide 1D Nanocomposites Y.C. Liang and Y.R. Cheng, Natl. Taiwan Ocean Univ., Taiwan	10P-7-46 Effect of Fe ₂ O ₃ on the Supercapacitive Property of ZnFe ₂ O ₄ F.O. Agyemang and H. Kim, Myongji Univ., Korea
10P-7-47 Synthesis of Carbon-CO ₃ O ₄ Nanorods Composite and Its Application towards Water Oxidation A.R. Jadhav, H.A. Bandal and H. Kim, Myongji Univ., Korea	10P-7-48 High Stable Electron Emission of Surface-Modified ZnO Nanowires S.-H. Yang and N.-C. Hsu, Univ. of Applied Sci., Taiwan	10P-7-49 Fabrication of Co ₃ O ₄ Nanotube Arrays by Using Cobalt/chitosan Precursor on ZnO Nanorod Array Templates Y.-C. Lee 1, H.-C. Yang 1, H.-H. Chou 1 and J.-C. Tsai 2, 1 Kun Shan Univ. and 2 Natl. Cheng Kuang Univ., Taiwan	10P-7-50 Study of Superior Photocatalytic and Photodetection Properties Using ZnO/ZnS Core-shell Nanorod Arrays Y.-R. Liu, S.-L. Tsai, S.-S. Lin, N.-C. Yu and C.-Y. Chen, Natl. Chi Nan Univ., Taiwan
10P-7-51 Solvothelmal Preparation and Electrochromic Properties of W ₁₈ O ₄₉ Nanowire Arrays on FTO Substrate C.-H. Lu 1, M.H. Hon 1, Y.-C. Lu 2 and I.-C. Leu 3, 1 Natl. Cheng Kung Univ., 2 Natl. Taiwan Univ. and 3 Natl. Univ. of Tainan, Japan	10P-7-52 Metal-Organic Framework Coated Nanocarbon Electrodes for Low-Temperature Lithium-ion Battery Y. Ishii, Y. Taniguchi and S. Kawasaki, Nagoya Inst. of Technol., Japan	10P-7-53 Design of Highly Efficient Thermoelectric Nanowires Based on First-Principles Electronic Structure K. Nakamura 1,2, 1 Kyoto Univ. and 2 Egypt-Japan Univ. of Sci. and Technol., Egypt	

Organic Nanomaterials

Chairperson: S. Takami (Tohoku Univ.)

10P-7-54 Nano Silver Particles Infiltrated Three-Dimensional Crimped Silk Yarn P. Wang, P. Zhang, Y.Y. Chen, H. Lin, D.S. Zhang, Y. Liu and Y. Zhang, Soochow Univ., China	10P-7-55 Preparation of TPP/ Magnetic Chitosan Nanoparticles as a Drug Delivery System H.-H. Chou, H.-C. Yang and Y.-C. Lee, Kun Shan Univ., Taiwan	10P-7-56 Technological Advanced by UV Irradiation of PEDOT Based Thin Film Using the Electrolysis Polymerization Method M. Takahashi, T. Deguchi and M. Takashiri, Tokai Univ., Japan	10P-7-57 Effects of Pluronic and Fibronectin on JSR Photo-induced Surface Control Polymer for Cell Culturing Template K.S. Kiang 1, A. Desalvo 1, S. Peters 2, K. Hoshiko 2, H. Hamaguchi 3, H. Morgan 1 and H.M.H. Chong 1, 1 Univ. of Southampton, UK, 2 JSR Micro NV, Belgium and 3 JSR, Japan
10P-7-58 Molecular Design of Radical-Functionalized Fullerene and Carbon Nanotubes (CNT): A DFT Study H. Tachikawa, T. Iyama and H. Kawabata, Hokkaido Univ., Japan	10P-7-59 Computer Aided-Molecular Design of Organic Radical-Functionalized Graphene: Density Functional Theory (DFT) Study T. Iyama, H. Kawabata and H. Tachikawa, Hokkaido Univ., Japan	10P-7-112L Synthesis and Adsorption Properties of Polymer-Mesoporous SiO ₂ Nanocomposite Based on Cellulose Biomass Via Self-Assembly J. Tao 1, J. Xiong 2, C. Jiao 1, Y. Chen 1 and H. Lin 1, 1 Soochow Univ., China and 2 Nanyang Technol. Univ., Singapore	10P-7-113L Withdrawn Rambutan Rind Extract Assisted Silver Nanoparticle Synthesis and Its Antibacterial Activity N. Yongvanich and S. Phongtongpasuk, Silpakorn Univ., Thailand

NanoTool

Chairperson: K. Sugano (Kobe Univ.)

10P-7-60 Nanopipette-Based Atomic Force Microscope for Nanofabrication T.S. Song, S. An, J. Whang and W. Jhe, Seoul Natl. Univ., Korea	10P-7-61 Cell Viability in Flash Freezing Method after Cryopreservation M. Shinose 1, A. Ueno 2, S. Yamaguchi 2 and Y. Akiyama 1, 1 Shinshu Univ. and 2 MICROJET, Japan	10P-7-62 Approach to Chromosome Structure by Ga FIB/SEM and Ne FIB/HIM S. Sasakura 1, A. Yoshida 2, K. Kaneyoshi 1, A. Dwiranti 1, H. Takata 1, S. Uchiyama 1, Y. Otsuka 2, S. Ogawa 1,3 and K. Fukui 1,4, 1 Osaka Univ., 2 Toray Res. Ctr., 3 AIST and 4 Tottori Univ., Japan	10P-7-63 Mixing and Blistering Phenomena in Etching Process of Gold Surface on Silicon Dioxide Layer Using Helium Ion Microscopy E. Maeda 1, T. Iijima 2, S. Migita 2, S. Ogawa 2 and R. Kometani 1, 1 Univ. of Tokyo and 2 AIST, Japan
---	--	---	--

<p>10P-7-64 Enhanced the Sensitivity of AFM Cantilevers by Controlling the Irradiated Configuration of Laser N.D. Vy 1, L.T. Dat 2, H.T. Huy 2 and T. Iida 3, 1 Ton Duc Thang Univ., 2 Ho Chi Minh City Univ. of Sci., Vietnam and 3 Osaka Pref. Univ., Japan</p>	<p>10P-7-65 Adhesion Measurement of Micro-patterned Surfaces Using 3D Printed AFM Tips C.-Y. Hung, Y.-P. Yeh, C.-K. Sung, W.-C. Liao, T.-H. Chuang and C.-C. Fu, Natl. Tsing Hua Univ., Taiwan</p>	<p>10P-7-66 Drift Compensation for Measuring Lattice Constant by Atomic Force Microscopy B.-C. He, I.-C. Lee, G.-J. Wu, and W.-E. Fu, ITRI, Taiwan</p>	<p>10P-7-67 Molecular-Scale Imaging of Two-Dimensional Streptavidin Crystals in Aqueous Solutions by Frequency-Modulation Atomic Force microscopy M. Miyamoto, H. Kominami, K. Kobayashi and H. Yamada, Kyoto Univ., Japan</p>
<p>10P-7-68 Development of Combined System of Pulsed Laser Deposition and Non-Contact Atomic Microscopy and High Resolution Imaging of Anatase-TiO₂(001) Reconstructed Surface D. Katsube 1, H. Yamashita 1,2, S. Abo 1, F. Wakaya 1 and M. Abe 1, 1 Osaka Univ. and 2 JST-PRESTO, Japan</p>	<p>10P-7-69 Molecular Scale Investigations of Hydration Structures of Hydrophilic Alkanethiol Self-Assembled Monolayers by FM-AFM A. Fujita, K. Kobayashi and H. Yamada, Kyoto Univ., Japan</p>	<p>10P-7-70 STM-Induced Light Emission Analysis of a Chiral Perylene Derivative on the Au(111) and NiAl(110) Surfaces N. Yajima, S. Chaunchaiyakul, P. Krukowski, M. Akai-Kasaya, A. Saito and Y. Kuwahara, Osaka Univ., Japan</p>	<p>10P-7-71 Optimization of Gold Nanorod Array Structure on Microresonator for Resonant-Based Laser Wavelength Measurement Using Photothermal Conversion K. Sugano 1, Y. Tanaka 1, E. Maeda 2, R. Kometani 2 and Y. Isono 1, 1 Kobe Univ. and 2 Univ. of Tokyo, Japan</p>
<p>10P-7-72 Single-Molecule Surface-Enhanced Raman Spectroscopy of 4,4'-bipyridine on Fabricated Substrates with Directionally Arrayed Gold Nanoparticle Dimers K. Sugano, K. Aiba, K. Ikegami and Y. Isono, Kobe Univ., Japan</p>	<p>10P-7-73 Optical Sensor Design Based on Bloch Surface Waves on One-Dimensional Photonic Crystal Substrate Y.-J. Hung and I.-S. Lin, Natl. Sun Yat-Sen Univ., Taiwan</p>		

Nanoimprint, Nanoprint and Rising Lithography

Chairperson: A. Miyauchi (Hitachi)

<p>10P-7-74 Prototype of Complementary Pattern Generator for Control of Residual Layer Uniformity in Nanoimprint Lithography S.-W. Youn, K. Suzuki and H. Hiroshima, AIST, Japan</p>	<p>10P-7-75 Study of Organic Thin Film Transistors with 3-D Finlike Channels Fabricated by Nanoimprint Technology H.J.H. Chen 1, T.-N. Lee 2, J.-S. Tang 1 and K.-C. Hsieh 2, 1 Natl. Chi Nan Univ. and 2 Natl. Tsing Hua Univ., Taiwan</p>	<p>10P-7-76 Growth of Aluminum Oxide on and in Imprinted Resin Patterns by an Atomic Layer Deposition Technique N. Hiroshiba, S. Kuroyanagi and M. Nakagawa, Tohoku Univ., Japan</p>	<p>10P-7-77 Evaluation of Thermal Nanoimprint Resin with PDMS Additive for Improving Release Property S. Fukui, M. Okada and Y. Haruyama, Univ. of Hyogo, Japan</p>
<p>10P-7-78 Fabrication of Nanogratings on Nanocellulose Films Using a Roll-to-Roll Nanoimprinting Method T. Mäkelä, M. Kainlahti, T. Tammelin and U. Forsström, VTT Technical Res. Ctr., Finland</p>	<p>10P-7-79 Nanoimprinting Silica Templates with Micro-, Sub-20-nm, and 7-nm Patterns Fabricated by Electron Beam Lithography S. Ito 1, E. Kikuchi 1, M. Watanabe 2, Y. Sugiyama 2 and M. Nakagawa 1, 1 Tohoku Univ. and 2 ELIONIX, Japan</p>	<p>10P-7-80 Nanoimprint of High Refractive Index Resin Composed of Episulfide Material K. Namiki, S. Fuse, E. Koshiishi and K. Furukawa, Mitsubishi Gas Chemical, Japan</p>	<p>10P-7-114L Fabrication of Self-Standing Thin Polystyrene Films with Through Holes by use of Imprint Process N. Sakamoto, H. Kawata, M. Yasuda and Y. Hirai, Osaka Pref. Univ., Japan</p>

BioMEMS, Lab on a Chip

Chairperson: A. Matsumoto (Tokyo Medical and Dental Univ.)

<p>10P-7-81 A Single Human Pluripotent Stem Cell Culture Platform L. Yu 1, J. Li 1, W. Yang 2, F. Tang 2, N. Fujimoto 1, M. Nakajima 1, Y. Chen 1,3, L. Liu 1 and H. Kotera 1, 1 Kyoto Univ., Japan 2 Peking Univ., China and 3 CNRS-ENS-UPMC, France</p>	<p>10P-7-82 Development of a Fluorescence Polarization-Based High-Throughput Assay System for Molecular Interaction Screening O. Wakao 1, M. Maeki 1, A. Ishida 1, H. Tani 1, A. Hibara 2 and M. Tokeshi 1, 1 Hokkaido Univ. and 2 Tohoku Univ., Japan</p>	<p>10P-7-83 Polymer Film-Based Flow Regulatory Valves for Disposable Microfluidics X. Zhang, G. Zhao, N. Xiang and Z. Ni, Southeast Univ., China</p>	<p>10P-7-84 Reconfigurable Microfluidic Channel Capable of Patterning of Cells M. Oono, A. Takano and N. Futai, Shibaura Inst. of Technol., Japan</p>
<p>10P-7-85 Label-Free Detection of Influenza Subtypes Based on Multisite Binding to Sialic Acid Receptors Immobilized Gold Electrode Y. Horiguchi, T. Goda, A. Matsumoto and Y. Miyahara, Tokyo Medical and Dental Univ., Japan</p>	<p>10P-7-86 Demonstration of ELISA on Steadily Rotating Centrifugal Microfluidic Device with Three-Dimensionally Extended Solid Phase S. Okamoto and Y. Ukita, Univ. of Yamanashi, Japan</p>	<p>10P-7-87 Neuronal Activity Evoked by Femtosecond Laser-Induced Stimulation C. Hosokawa 1, Y. Nakagawa 1,2, S.N. Kudoh 2 and T. Taguchi 3, 1 AIST, 2, Kwansei Gakuin Univ. and 3 NICT, Japan</p>	<p>10P-7-88 Evaluation of the Diffusion Progress in the Microfluidic Static Gradient Generator M. Tamura 1, Y. Shiota 1, A. Yoshino 1, T. Ogawa 2, A. Takano 1 and N. Futai 1, 1 Shibaura Inst. of Technol. and 2 Tokyo Medical and Dental Univ., Japan</p>

Microsystem Technology and MEMS

Chairperson: T. Namazu (Aichi Inst. of Technol.)

<p>10P-7-89 The Development of a Resonant Temperature Micro-Sensor by Electroforming Process Y.-H. Lin 1, Y.-C. Shieh 2, C.-C. Chen 1, C.-N. Hsiao 1, M.-H. Shiao 1 and C.-T. Lin 1, 1 Natl. Applied Res. Labs. and Natl. Chiao Tung Univ., Taiwan</p>	<p>10P-7-90 Dependency of Microstructure on Exothermic Characteristics for Al/Ni Multilayer Materials Based on Cold-rolled Method N. Kametani 1, T. Izumi 1, S. Miyake 1, S. Kanetsuki 1,2 and T. Namazu 2, 1 Kobe City College of Technol. and 2 Aichi Inst. of Technol., Japan</p>	<p>10P-7-91 Thermoplasmonic Marangoni Flow Around a Microbubble in Degassed Water K. Namura, K. Nakajima and M. Suzuki, Kyoto Univ., Japan</p>	<p>10P-7-92 Fabrication of Thin-Film Thermoelectric Generators with Ball Lenses for Conversion of Near-infrared Solar Energy Y. Ito, M. Mizoshiri, M. Mikami, J. Sakurai and S. Hata, Nagoya Univ., Japan</p>
<p>10P-7-93 Fabrication of Ni/Cr₂O₃ Composite Microstructures Using Femtosecond Laser Reductive Sintering of NiO/Cr Mixed Nanoparticles K. Tamura, M. Mizoshiri, J. Sakurai and S. Hata, Nagoya Univ., Japan</p>	<p>10P-7-94 Microscale Phloem Sap Dynamics Measurement Sensor Device for Monitoring the Transport of Nutritive Substances in Plant Shoots A. Ono 1, Y. Yano 2, K. Terao 1, H. Takao 1, R. Ichihashi 2, T. Kobayashi 2, I. Kataoka 2 and F. Shimokawa 1, 1 Kagawa Univ. and 2 Mitsubishi Electric, Japan</p>	<p>10P-7-95 Optimisation of Subthreshold Leakage Current in Resonant Gate Transistor R. Latif 1,2, B.Y. Majlis 2 and R. Cheung 1, 1 Univ. of Edinburgh, UK and The Natl. Univ. of Malaysia, Malaysia</p>	<p>10P-7-96 X-ray Evaluation of High Verticality Sidewalls Fabricated with Deep Reactive Ion Etching K. Takeuchi 1, Y. Ezoe 1, K. Ishikawa 2, K. Nakamura 1, M. Numazawa 1, M. Terada 1, M. Fujitani 1, D. Ishii 1, Y. Noda 1, T. Ohashi 1, K. Morishita 3, K. Nakajima 4 and K. Mitsuda 2, 1 Tokyo Metropolitan Univ., 2 ISAS/JAXA, 3 Kyoto Univ. and 4 JST, Japan</p>
<p>10P-7-97 Floating Thin-membrane Based SAW Gyroscope for Higher Sensitivity M.H. Lee, H.S. Choi, C.H. Choi and K.K. Lee, Ajou Univ., Korea</p>	<p>10P-7-98 Enhancement of Efficiency for Power Generation of a Plate-Type Thermoelectric Power Generator by Stacking the Thermoelectric Plates T. Daimon and H. Tohmyoh, Tohoku Univ., Japan</p>	<p>10P-7-99 Fabrication of Thick Glass Layers for Thermal Isolation by Glass Reflow Process N.V. Toan and T. Ono, Tohoku Univ., Japan</p>	<p>10P-7-115L LiNbO₃/Si Hybrid Wafer Bonded in Ambient Air Using Laser Irradiation R. Takigawa, H. Kawano, H. Ikenoue and T. Asano, Kyushu Univ., Japan</p>
<p>10P-7-116L Development of a Small RF Variable Capacitor Integrated with Automatic Fluid Carrying System S. Kanazawa 1, T. Nishihara 1, Y. Shibasaki 2, Y. Ogawa 2, H. Fujii 1, T. Furutsuka 1 and K. Suzuki 1, 1 Ritsumeikan Univ. and 2 Taiyo Ink, Japan</p>			

Room A (Heian 3,4, 2F)

18:20-20:20**Banquet**

Friday November 11

Room A (Heian 4, 2F)	Room B (Suzaku 2, 2F)	Room C (Suzaku 1, 2F)	Room D (Daigo, 2F)
11A-8: Symp. A: Metrology and Inspection for Advanced Patterning S. Nagahara (Tokyo Electron) A. Yamaguchi (Hitachi)	11B-8: Inorganic Nanomaterials II M. Suzuki (AIST) T. Taniguchi (NIMS)	11C-8: Nano Resistive and Atomic Switching Devices T. Yanagida (Kyushu Univ.) N. Banno (NEC)	11D-8: BioMEMS, Lab on a Chip I T. Akagi (Univ. of Tokyo) K. Tawa (Kwansei Gakuin Univ.)
11A-8-1 9:00 Metrology and Inspection for Next Generation Lithography (Invited) M. Asano, Toshiba, Japan	11B-8-1 9:00 Nature of BaTiO ₃ Nanocubes for Self-Assembly and Dielectric Abnormally (Invited) K. Kato, K. Mimura, Q. Ma, Z. Liu and K. Yasui, AIST, Japan	11C-8-1 9:00 Conductance Quantization in Binary-Oxide-Based ReRAM Cells (Invited) Y. Nishi, H. Sasakura, Y. Kuriyama and T. Kimoto, Kyoto Univ., Japan	11D-8-1 9:00 Cell-Generated Niches for Organ-on-a-Chip Microdevices (Invited) Y. Torisawa, Kyoto Univ., Japan
11A-8-2 9:30 Current and Future Requirements for Metrology and Inspection for Advanced Patterning (Invited) P. Leray, A.L. Charley, P. Wong, S. Halder and P. Foubert, imec, Belgium	11B-8-2 9:30 Universal Design Rule for Single Crystalline Oxide Nanowires Growth K. Nagashima 1, H. Anzai 1, D. Sakai 1, Z. Zhu 1, A. Inoue 1, C. Nakamura 1, A. Klamchuen 2, M. Suzuki 1, H. Yoshida 3, M. Kanai 1, G. Meng 1, F.W. Zhuge 1, Y. He 1, S. Takeda 3, T. Kawai 3 and T. Yanagida 1, 1 Kyushu Univ., Japan, 2 NANOTEC, Thailand and Osaka Univ., Japan	11C-8-2 9:30 Resistive Switching Mechanisms in Memristors with TiO ₂ /Al ₂ O ₃ Bilayer Structures L. Alekseeva 1, M. Baranovskii 1, V. Luchinin 1, A. Petrov 1, T. Chikyow 2 and T. Nabatame2, 1 St. Petersburg Electrotechnical Univ., Russia and 2 NIMS, Japan	11D-8-2 9:30 Development of a Microfluidic Probe Integrated Device for High Resolution Spatial Chemical Stimulation Control K. Shinha 1, M. Horayama 1, T. Fujii 2 and H. Kimura 1, 1 Tokai Univ. and 2 Univ. of Tokyo, Japan
11A-8-3 10:00 Outlook of Mask Registraton and Required Metrology Technology (Invited) K.-D. Roeth, KLA, Germany	11B-8-3 9:50 Highly Organized Layer-by-Layer Assembly of Perovskite Ferroelectric Superlattices M.S. Khan 1,2, M. Osada 1,2, Y. Ebina 1 and T. Sasaki 1, 1 NIMS and 2 Waseda Univ., Japan	11C-8-3 9:50 p-type Polymer-Based Ag ₂ S Atomic Switch for 'Tug of War' Operation C. Lutz 1,2, T. Hasegawa 1 and T. Chikyow 2, 1 Waseda Univ. and 2 NIMS, Japan	11D-8-3 9:50 A Prime-Boost Vaccination Strategy Based on Chitosan/Gamma-Polyglutamic Acid Microneedle Patches with a Two-Stage Release Profile M.-C. Chen and Y.-Y. Chen, Natl. Cheng Kung Univ., Taiwan
11A-8-4 10:30 Electron-Beam Metrology and Inspection: Scaling, Variability, and Productivity (Invited) Y. Momono and H. Fukuda, Hitachi High-Technologies, Japan	11B-8-4 10:10 Crystal Orientation Dependence of Bi-layered Ferroelectric Nanostructures in Epitaxial Pillar-Matrix Nanocomposite Films Y. Kawahira, S. Maruyama and Y. Matsumoto, Tohoku Univ., Japan	11C-8-4 10:10 Quantized Conductance Operation Near a Single-Atom Point Contact in a Polymer-Based Atomic Switch K. Krishnan, T. Tsuruoka and M. Aono, NIMS, Japan	11D-8-4 10:10 Measurement of the Surface Protein Level and Diameter of Individual Extracellular Vesicles of Human Breast Cancer Cells on a Microfluidic Chip T. Akagi 1, H. Kishita 1, Y. Suehiro 1, S. Oniyana 1 and T. Ichiki 1,2, 1 Univ. of Tokyo and 2 iCONM, Japan
	11B-4: Author's Interview: 11:55-12:05	11C-4: Author's Interview: 12:05-12:15	11D-8: Author's Interview: 11:55-12:05
Room P (Heian 1,2,3, 2F)			
Coffee Break			
Room A (Heian 4, 2F)	Room B (Suzaku 2, 2F)	Room C (Suzaku 1, 2F)	Room D (Daigo, 2F)
11A-9: Advanced Photolithography J. Miyazaki (ASML) T. Sato (Toshiba)	11B-9: Inorganic Nanomaterials III T. Taniguchi (NIMS) J. Hamagami (Kanto Gakuin)	11C-9: Nanosensor Devices K. Takei (Osaka Pref. Univ.) T. Yanagida (Kyushu Univ.)	11D-9: BioMEMS, Lab on a Chip II H. Nagai (AIST) Y. Takamura (JAIST)
11A-9-1 11:15 Readiness of EUV Lithography and Its Impacts on Design and Patterning of Backend Layers for 5nm Node and Beyond (Invited) T.-B. Chiou 1, A. Chen 2 and M. Dusa 2, 1 ASML Taiwan, Taiwan and 2 ASML US, USA	11B-9-1 10:45 Laser Ablation in Liquid: from Nanocrystals Synthesis to Nanostructures Fabrication (Invited) G.W. Yang, Sun Yat-sen Univ., China	11C-9-1 10:45 Acetone Sensing by Graphene Sensor H. Nemoto, R. Ueki, Q. Fang, T. Matsuki, R. Fukui and S. Warisawa, Univ. of Tokyo, Japan	11D-9-1 10:45 Combination of Microdevices and Biological Cells to Create Novel Principle Devices (Invited) Y. Tanaka, RIKEN, Japan
11A-9-2 11:45 Development of 250w 13.5nm LPP-EUV Light Source for HVM Lithography J. Fujimoto, T. Saito and H. Mizoguchi, Gigaphoton, Japan	11B-9-2 11:15 A Dual-Mode Substrate Based on Ultrathin Silica Coated Silver Nanocubes and Modified Aluminum Sheet for Biomolecular Detection N.M. Kha 1, W.-N. Su 1 and B.-J. Hwang 1,2, 1 Natl. Taiwan Univ. of Sci. and Technol. and 2 Natl. Synchrotron Radiation Res. Ctr., Taiwan	11C-9-2 11:05 Effect of Yttrium Content and Thermal Annealing on the Structural Properties and Sensing Characteristics of YbY _x O _y Sensing Membranes T.-M. Pan 1, C.-W. Wang 1, H.-C. Wang 1 and L. Chi 2, 1 Chang Gung Univ., Taiwan and 2 Westfälische Wilhelms Univ. Münster, Germany	11D-9-2 11:15 Patterning of Kinesin Molecules on Au Nano-Pillars by Selective SAM Coatings T. Kaneko, S. Ando, H. Shintaku, H. Kotera and R. Yokokawa, Kyoto Univ., Japan

11A-9-3 12:05 Process-Induced Variability in Multiple Patterning Extension M. Yamato, A. Hara, S. Natori, K. Koike, S. Yamauchi, K. Oyama and H. Yaegashi, Tokyo Electron, Japan	11B-9-3 11:35 Characterization of Cu ₂ ZnSnSe ₄ Nanoparticles Prepared at Various Temperatures T. Suzuki 1, T. Suzuki 2, S. Hori 2 and S. Nonomura 2, 1 Japan Fine Ceramics Ctr. and 2 Gifu Univ., Japan	11C-9-3 11:25 Design and Fabrication of Polymer-based Photonic Crystal Waveguide for Sensing Application J. Sun, H. Hisamoto, K. Sueyoshi and T. Endo, Osaka Pref. Univ., Japan 11C-9-4 11:45 Voltammetric Detection of Hydrochlorothiazide Using Functionalized CNT K.K. Reddy and H. Kim, Myongji Univ., Korea	11D-9-3 11:35 Application of a Bull's Eye-plasmonic Chip to Highly Sensitive Bio-detection with a Microscope S. Izumi 1, M. Toma 1, C. Hosokawa 2 and K. Tawa 1,2, 1 Kansei Gakuin Univ. and 2 AIST, Japan
11A-9: Author's Interview: 12:25-12:35	11B-9: Author's Interview: 11:55-12:05	11C-9: Author's Interview: 12:05-12:15	11D-9: Author's Interview: 11:55-12:05
Lunch			
Room A (Heian 4, 2F)	Room B (Suzaku 2, 2F)	Room C (Suzaku 1, 2F)	Room D (Daigo, 2F)
11A-10: Resist and Directed Self-Assembly T. Nagai (JSR) T. Azuma (Toshiba)	11B-10: Inorganic Nanomaterials IV J. Hamagami (Kanto Gakuin) M. Suzuki (AIST)	11C-10: Nano Devices T. Maemoto (Osaka Inst. of Technol.) Y. Hotta (Univ. of Hyogo)	11D-10: Microsystem Technology and MEMS III S. Nagasawa (Shibaura Inst. of Technol.) M. Ikeuchi (Univ. of Tokyo)
11A-10-1 14:00 Directed Self-Assembly of High- χ Block Copolymers (<i>Invited</i>) A. Vora, N. Arellano, K. Schmidt, D.P. Sanders and R.D. Allen, IBM Research Almaden, USA	11B-10-1 13:30 Preparation of Graphene Oxide-Coated Silk Fibers through HBPA Induced Layer-by-Layer Self-assembly J. Song 1,2, S. Xu 1, T. Chen 2, S. Yamanaka 1 and H. Morikawa 1, 1 Shinshu Univ., Japan and 2 Jiang Univ. of Sci. & Technol., China	11C-10-1 13:30 Structural Properties and Electrical Characteristics of Sm ₂ TiO ₅ Gate Dielectrics for InGaZnO Thin-Film Transistors T.-M. Pan 1, H.-C. Wang 1, Y.-H. Huang 1, C.L. Chan 1, J.-L. Her 1 and K. Koyama 2, 1 Chang Gung Univ., Taiwan and 2 Kagoshima Univ., Japan	11D-10-1 13:30 Tactile Display for Stiffness Distribution Using Magnetorheological Fluid Array H. Ishizuka 1 and N. Miki 2, 1 Kagawa Univ. and 2 Keio Univ., Japan
11A-10-2 14:30 A Molecular Dynamics Analysis on PS-Brush Surface Modification for Pre-Treatment of DSA T. Nakano 1 and M. Muramatsu 2, 1 Tokyo Electron and 2 Tokyo Electron Kyushu, Japan	11B-10-2 13:50 Pulse-induced Resistive Switching Device of Pt/TiO _{2.5} /Pt Cross-Point Structure with Electron-Ion Mixed Conduction K. Kawamura 1, T. Tsuchiya 2, M. Takayanagi 1, M. Minohara 3, M. Kobayashi 3, K. Horiba 3, H. Kumigashira 3, K. Terabe 2 and T. Higuchi 1, 1 Tokyo Univ. of Sci., 2 NIMS and 3 KEK, Japan	11C-10-2 13:50 Impact of Ti Content on Electrical Characteristics of ErTi _x O _y Charge Storage Layer in InGaZnO Thin-Film Transistor Nonvolatile Memories T.-M. Pan, C.-H. Chen, Y.-H. Hu and J.-L. Her, Chang Gung Univ., Taiwan	11D-10-2 13:50 Development of a Fully Flexible Micro-stimulation Electrode Tip R. David and N. Miki, Keio Univ., Japan
11A-10-3 14:50 Sensitivity Enhancement of Chemically Amplified EUV Resist by Adding Acid Generation Promoters S. Fujii 1, K. Okamoto 1, H. Yamamoto 2, T. Kozawa 2 and T. Itani 3, 1 Hokkaido Univ., 2 Osaka Univ. and 3 EIDEC, Japan	11B-10-3 14:10 Structural and Magnetic Domain Characterization of Lateral MnAs Nanowires R. Horiguchi, H. Kato, K. Kabamoto, R. Kodaira and S. Hara, Hokkaido Univ., Japan	11C-10-3 14:10 Temperature Dependence of Gate-all-around Poly-Si Nanowire Junctionless Transistors with Multiple Channels and Sub-50 nm Twin Gate C.-T. Tso, T.-Y. Liu, F.-M. Pan and J.-T. Sheu, Natl. Chiao Tung Univ., Taiwan	11D-10-3 14:10 Breathing Signal Analysis of Mouse during Drug Inhalation H. Kawaoka 1, Y. Hasegawa 1, M. Matsushima 2, T. Kawabe 2 and M. Shikida 1, 1 Hiroshima City Univ. and 2 Nagoya Univ., Japan
	11B-10-4 14:30 Shape Control of Ferromagnetic MnAs Nanoclusters and Their Magnetization in Semiconducting InAs Nanowires R. Kodaira, K. Kabamoto and S. Hara, Hokkaido Univ., Japan	11C-10-4 14:30 Molecular Dynamics Study on Dipole Layer Formation at High-k/SiO ₂ Interface: Possibility of Oxygen Ion Migration Induced by the Imbalance of Multipole Potentials- R. Kunugi, N. Nakagawa and T. Watanabe, Waseda Univ., Japan	11D-10-4 14:30 Effect of Guide Tube Length on Sensor Output in Inspired Airflow Measurement Y. Hasegawa 1, N. Harada 1, M. Matsushima 2, T. Kawabe 2 and M. Shikida, 1 Hiroshima City Univ. and 2 Nagoya Univ., Japan
	11B-10-5 14:50 Nanoscale Liquid as a Novel Nanomaterial and Its Atomic Force Microscopic Study M. Lee, S. An, T.S. Song and W. Jhe, Seoul Natl. Univ., Korea	11C-10-5 14:50 MEMS Fabricated Conformal Electrodes Attempting Thermotunnelling Refrigeration A. Banerjee, Y. Hirai, T. Tsuchiya and O. Tabata, Kyoto Univ., Japan	11D-10-5 14:50 Finger-tip Size Quantitative Real-time PCR Device for Early Detection of Cancer 2nd Report: The Detection of Cancer Specific MicroRNA Y. Kimura, M. Ikeuchi and K. Ikuta, Univ. of Tokyo, Japan
11P-10: Author's Interview: 15:10-15:20	11B-10: Author's Interview: 15:10-15:20	11C-10: Author's Interview: 15:10-15:20	11D-10: Author's Interview: 15:10-15:20

11P-11: 15:20-17:20 POSTER SESSION II**Advanced Photolithography**

Chairperson: J. Miyazaki (ASML)

11P-11-1 Actinic EUV Mask Inspection using Coherent EUV Light from High Harmonic Generation B. Moon 1,2, Y.S. Kim 3, Y.T. Kim 1, H. Sung 4, J. Kim 4, B.-K. Ju 2 and Y.M. Jhon 1, 1 KIST, 2 Korea Univ., 3 Hanmi Semiconductor and 4 Laser Spectronix, Korea	11P-11-98L Optimization of High Harmonic Generation of Coherent EUV Light for EUV Metrology: Simulations and Experiments M.K. Jung 1,2, Y.S. Kim 3, Y. Kim 1, Y.T. Kim 1, H. Sung 4 and J. Kim 4, J.H. Lee 2 and Y.M. Jhon 1, 1 KIST, 2 Univ. of Seoul, 3 Hanmi Semiconductor and 4 Laser Spectronix, Korea	11P-11-99L Improvement of Mask-Defect-Detection Performance of Coherent EUV Scatterometry Microscope with High-Harmonic-Generation EUV Source D. Mamezaki 1, T. Harada 1, Y. Nagata 2 and T. Watanabe 1, 1 Univ. of Hyogo and 2 RIKEN, Japan	
---	--	---	--

Resist and Directed Self-Assembly

Chairperson: K. Yoshimoto (Kyoto Univ.)

11P-11-2 Dependence of Dissolution Kinetics of ZEP 520A on Change of Molecular Weight Induced by Electron Beam Irradiation A. Konda 1, H. Yamamoto 1, T. Kozawa 1 and S. Yoshitake 2, 1 Osaka Univ., and 2 NuFlare Technol., Japan	11P-11-3 In-situ Measurement of Outgassing Generated from EUV Resist Including Metal Oxide Nanoparticles During Electron Irradiation S. Takahashi 1, Y. Minami 1, M. Kaboi 1, Y. Matsumoto 1, A. Sekiguchi 1 and T. Watanabe 2, 1 Litho Tech Japan and 2 Univ. of Hyogo, Japan	11P-11-4 Removal of SU8 with N-Methyl-2-Pyrrolidone Doping LiCl and H ₂ O M. Yasui 1, H. Nakano 2, M. Kurouchi 1, T. Ozawa 1, S. Kawano 2 and S. Kaneko 1, 1 Kanagawa Industrial Technol. and 2 Nomura Micro Sci., Japan	11P-11-5 Controllable Micro-Optical Element Molds Fabricated by Self-Assembly and Metal-Assisted Chemical Etching P. Jin, Y. Han, A. Jin and A. Wang, Harbin Inst. of Technol., China
11P-11-6 Polysaccharide Block Copolymers Made from Woods for the Contact Hole and L/S Applications on Directed Self-Assembly Lithography K. Morita and K. Yamamoto, Oji Holdings, Japan	11P-11-7 PMMA-Selective Organic-Inorganic Hybridization Using Cylindrically Micro-Phase Separated PS- <i>block</i> -PMMA N. Hiroshiba and M. Nakagawa, Tohoku Univ., Japan		

Nanocarbons

Chairperson: S. Okada (Univ. of Tsukuba)

11P-11-8 A Top-Down Strategy towards Single-Digit Nanodiamonds J. Xiao and G.W. Yang, Sun Yat-sen Univ., China	11P-11-9 Electronic Structure of CNT Thin Films with Nanoscale Interfaces under an Electric Field T. Kochi and S. Okada, Univ. of Tsukuba, Japan	11P-11-10 Characterization of Coke, or Carbonaceous Matter, Formed on CoMo Catalysts Used in Hydrodesulfurization Unit in Oil Refinery N. Kimura, Y. Iwanami, R. Koide and R. Kudo, JX Nippon Oil and Energy, Japan	11P-11-11 Energetics and Electronic Structures of Molecular Complexes Consisting of Large Fullerene and Cyclohydrocarbon Y. Nagasawa and S. Okada, Univ. of Tsukuba, Japan
11P-11-12 Stretchable Fiber-Typed Supercapacitors Based on Carbon Fiber Electrodes Decorated with Three-Dimensional Carbon Nanotube-Graphene Hybrid Networks N. Kim, H. Cha, W. Lee and Y. Oh, KIMS, Korea	11P-11-13 Synthesis of Highly Aligned Carbon Nanotubes by One-Step Liquid-phase Process: Effects of Carbon Sources on Morphology of Carbon Nanotubes K. Yamagiwa 1, Y. Ayato 2 and J. Kuwano 3, 1 Teikyo Univ. of Sci., 2 Shinshu Univ. and 3 Tokyo Univ. of Sci., Japan	11P-11-14 Electrospun Carbon Nanofibers/nickel Hydroxide Composites as Supercapacitor Electrodes C.-T. Lo and C.-C. Lai, Natl. Cheng Kung Univ., Taiwan	11P-11-15 Carbon Nanodots/silicon Nanowires Heterostructures for Efficient Photodegradation of Dyes P.-H. Hsiao, B.-S. Chen and C.-Y. Chen, Natl. Chi Nan Univ., Taiwan
11P-11-16 Protein Adsorption Characteristics on Bare and Phosphorylcholine-Modified Graphene Film on SiC Substrate Y. Taniguchi, T. Miki, T. Mituno, Y. Ohno, M. Nagase, K. Minagawa and M. Yasuzawa, Tokushima Univ., Japan	11P-11-17 Work Function Modulation of Edge Functionalized Graphene Nanoflakes R. Taira, A. Yamanaka and S. Okada, Univ. of Tsukuba, Japan	11P-11-18 Energetics and Electronic Structure of h-BN Nanoribbons A. Yamanaka and S. Okada, Univ. of Tsukuba, Japan	11P-11-19 High Performance Heat-Treated Mono-Layer Graphene-Based Hybrid Photo-Voltaic Device S.M. Sanip and M.S. Shamsudin, Univ. of Southampton Malaysia, Malaysia
11P-11-20 Engineering Function Groups in Graphene Oxide T. Taniguchi 1, M. Osada 1, K. Hatakeyama 2 and Y. Matumoto 2, 1 NIMS and 2 Kumamoto Univ., Japan	11P-11-21 Initial Stage of h-BN Growth in Diffusion and Precipitation Method S. Suzuki, Y. Ogawa, S. Wang and K. Kumakura, NTT, Japan	11P-11-22 Porous Hydrocarbon Networks of Pyramidal Molecules J. Sorimachi and S. Okada, Univ. of Tsukuba, Japan	11P-11-23 Effect of Metal Nanoparticles on Carrier Accumulation in Graphene under an Electric Field M. Matubara and S. Okada, Univ. of Tsukuba, Japan

11P-11-24 Carrier Doping Effect of Humidity for Single-Crystal Graphene on SiC M. Kitaoka, T. Nagahama, K. Nakamura, T. Aritsuki, K. Takashima, Y. Ohno and M. Nagase, Tokushima Univ., Japan	11P-11-25 Kondo Effect in Graphene Quantum Dots Y. Kanai 1, T. Ono 1, Y. Ohno 1,2, K. Maehashi 1,3, K. Inoue 1, and K. Matsumoto 1, 1 Osaka Univ., 2 Tokushima Univ. and 3 Tokyo Univ. of Agriculture and Technol., Japan	11P-11-26 Energetics and Electronic Properties of a Hexagonally Bonded Sheet of GaN Under Biaxial Compression Y. Gao and S. Okada, Univ. of Tsukuba, Japan	11P-11-100L Platform for Electrical Measurement of π -Conjugated Polymer Wire with Graphene Nanogap Electrodes T. Ikuta 1, S. Tamba 1, Y. Kanai 1, Y. Ohno 1,2, K. Maehashi 1,3, K. Inoue 1, Y. Ie 1, Y. Aso 1 and K. Matsumoto, 1 Osaka Univ., 2 Univ. of Tokushima and 3 Tokyo Univ. of Agriculture and Technol., Japan
11P-11-101L Locally Pinned Free Standing Graphene Growth on C-face 4H-SiC{1-10n} Y. Kutsuma, D. Dojima, K. Ashida and T. Kaneko, Kwansai Gakuin Univ., Japan			
Nanodevices			
Chairperson: Y. Ishikawa (Nara Inst. of Sci. and Technol.)			
11P-11-27 Preliminary Study on Origin of Low and Broad V_{th} Fluctuation on Low- V_{th} Side Caused by Ion Implantation to Source and Drain Extensions of SOI Tri-Gate FinFET Using 3D Process and Device Simulations T. Tsutsumi, Meiji Univ., Japan	11P-11-28 Fabrication and Characterization of Silicon Notched Nanowire FETs with Selective Channel Dopants Z. Tan 1, T. Iwasaki 1,2, L. Boodhoo 1, H. Mizuta 1,2 and H.M.H. Chong 1, 1 Univ. of Southampton, UK and 2 JAIST, Japan	11P-11-29 Channel Shape Effects on the Electrical Characteristics of FinFETs I.-C. Lee 1, B.-C. He 1, Y.-S. Chien 1, W.-E. Fu 1, Y.-C. Wei 2, J.-D. Luo 2, K.-C. Chuang 2, H.-C. Cheng 2, 1 ITRI and 2 Natl. Chiao Tung Univ. Taiwan	11P-11-30 Nanocrystalline Graphite Coated SOI Nano-Electromechanical Switches L. Boodhoo 1, S. Rana 2, Y. Tsuchiya 1, W. Redman-White 1, S.H. Pu 1,3, H. Mizuta 1,4, D. Pamunuwa 2 and H.M.H. Chong 1, 1 Univ. of Southampton, 2 Univ. of Bristol, UK, 3 Univ. of Southampton Malaysia, Malaysia and 4 JAIST, Japan
11P-11-31 Simulation and Technical Feasibility Study of 80 nm Asymmetric T Shape Gate for High Breakdown Voltage at High Operation Frequency in GaN HEMTs J. Shao, J. Deng, X. Huang, S. Zhang and Y. Chen, Fudan Univ., China	11P-11-32 Capacitorless 1T-DRAM Based on Double-Gate GaAs Junctionless Transistor Y.J. Yoon, J.H. Seo, Y.I. Jang, M.S. Cho, J.-H. Lee and I.M. Kang, Kyungpook Natl. Univ., Korea	11P-11-33 Charge Retention in Vertical van der Waals Heterostructure Encapsulated Semi-Metallic Graphene D. Chu and E.-K. Kim, Hanyang Univ., Korea	11P-11-34 Controlling Carrier Injection of QLEDs by Introducing Graphene Oxide Quantum Dots Doped PEDOT:PSS C.-C. Wu 1, H.-C. Yu 1 and Y.-K. Su 1,2, 1 Natl. Cheng-Kung Univ. and 2 Kun-Shan Univ., Taiwan
11P-11-35 Improvement of Quantum-Confinement Stark Effect in InGaN/GaN Blue Light-Emitting Diodes with Partial Quantum Barrier Si-doping Y.H. Hsu, Y.Z. Chiou and C.K. Wang, Southern Taiwan Univ. of Sci. and Technol., Taiwan	11P-11-36 Improved Metal Migration of the Electrode Reflector for GaN-Based Blue Light Emitting Diodes Y.Y. Chen, Y.Z. Chiou and C.K. Wang, Southern Taiwan Univ., Taiwan	11P-11-37 High-Performance P-Channel Thin-Film Transistors on Lightly Doped N-Type Excimer-Laser-Crystallized Germanium Films C.-Y. Liao, C.-Y. Huang, M.-H. Huang and H.-C. Cheng, Natl. Chiao Tung Univ., Taiwan	11P-11-38 Silicon Carbide Nanostructured Field Emission Array A.S. Ivanov, V.A. Ilyin, V.V. Luchinin and V.N. Titov, St. Petersburg Electrotechnical Univ., Russia
11P-11-39 One-Dimensional Photonic Crystal Nanocavity with Monolayer Molybdenum Disulfide (MoS ₂) for Enhanced Light-Matter Coupling H. Qiu 1, T. Liu 1, T. Ying 1, C. Huang 2, G. Liang 1, B. Qiang 1, Y. Shen 1, N. Taksatorn 3, H. Wang 1, Z. Shen 1, Q. Wang 1, 1 Nanyang Technol. Univ., Singapore, 2 Univ. of Southampton, UK and 3 Genlsys, Germany	11P-11-40 Self-capacitance of Atomic and Molecular Scale Devices: Properties and Scope of Applications P. Szarek, Univ. of Warsaw, Poland	11P-11-41 Enhanced Fluorescence Detection of Fluoride Ions via Nanometallic Plasmonic Effect R. Appiah-Ntiamoah, B. Tesfaye and H. Kim, Myongji Univ., Korea	11P-11-42 Optical and Electrochemical Performance of a Novel ZrO ₂ -IPTES- <i>graft</i> -PVdF/HFP Nanocomposite Polymer Electrolyte in Electrochromic Devices J.M.C. Puguang and H. Kim, Myongji Univ., Korea
11P-11-102L Self-Rectifying and Forming Free Stable Resistive Switching Behavior Observed in HfO ₂ -Based Memory by Quantum Tunneling Mechanism M. Yun, S. Kim and H.-D. Kim, Sejong Univ., Korea	11P-11-103L Extremely Thin Metal-Insulator-Semiconductor Diode Consist of 2D Nanomaterials H. Jeong 1,2, H.M. Oh 1, S. Bang 1, H.J. Jeong 1, S.-J. An 1, G.H. Han 1, H. Kim 1, K.K. Kim 3, J.C. Park 1, Y. Kim 4, Y.H. Lee 1, G. Lerondel 1,2 and M.S. Jeong 1, 1 Sungkyunkwan Univ., Korea, 2 Univ. de Technologie de Troyes, France, 3 Dongguk Univ. and 4 Dankook Univ., Korea	11P-11-104L Improving Read Disturbance in Channel Stacked NAND Flash Memory with Layer Selection by Multilevel Operation D.-B. Kim 1, D.W. Kwon 1, B.-S. Jo 2, G.S. Cho 2, S.-K. Park 2 and B.-G. Park 1, 1 Seoul Natl. Univ. and 2 SK Hynix, Korea	11P-11-105L Investigation of Silicide Induced Dopant Activation for Steep Tunnel Junction in Tunneling Field Effect Transistor (TFET) S. Kim, D.W. Kwon, E. Park, J. Lee, R. Lee, J.-H. Lee and B.-G. Park, Seoul Natl. Univ., Korea

11P-11-106L Comparative Investigation on Platinum and Titanium Thermistors for Room-Temperature Antenna-Coupled Terahertz Microbolometer Application A. Banerjee, H. Satoh, T. Ajay, N. Hiromoto and H. Inokawa, Shizuoka Univ., Japan	11P-11-107L Back-Gate Effect on Multi-Channel Nanowire Tunnel Field-Effect Transistors (TFETs) for Modulating Turn-on Point E. Park, D.W. Kwon, J. Lee, S. Kim, R. Lee, J.-H. Lee and B.-G. Park, Seoul Natl. Univ., Korea	11P-11-108L Demonstration of Reconfigurable Field Effect Transistor (RFET) for 3D Stacked TFET Application R. Lee, D.W. Kwon, J. Lee, E. Park, S. Kim and B.-G. Park, Seoul Natl. Univ., Korea	11P-11-109L Capacitor-Less DRAM Cell Using Thyristor Vertically Fabricated with Polycrystalline Silico D.W. Kwon, E. Park, J. Lee, R. Lee, S. Kim, H.M. Kim and B.-G. Park, Seoul Natl. Univ., Korea
---	---	---	---

Nanofabrication

Chairperson: K. Tomioka (Hokkaido Univ.)

11P-11-43 Study on Direct Patterning Method of the Oxide Materials without Using Photolithography, Photoresist and Plasma Etching Y. Yoshimoto, J. Li and T. Shimoda, JAIST, Japan	11P-11-44 Sensitized Mass Change Detection by Using Au Nanoporous Electrode for Biosensing H. Terasawa, N. Asai, T. Shimizu, S. Shingubara and T. Ito, Kansai Univ., Japan	11P-11-45 Cerium Iron Oxide Nanorods Shape Evaluation for Epoxide Opening Reaction through Azide Addition A.A. Chaugule, H.A. Bandhal and H. Kim, Myongji Univ., Korea	11P-11-46 Preparation and Characterization of Silver Nanoparticles in Methyl Cellulose Matrix K. Kolarova, D. Samec, A. Reznickova, S. Rimpelova and V. Svorcik, Univ. of Chemistry and Technol., Czech
11P-11-47 Nano-Porous Lattice Biosensor Using Anodic Aluminum Oxide Substrate Y. Matsuda, N. Asai, T. Shimizu, S. Shingubara and T. Ito, Kansai Univ., Japan	11P-11-48 Novel Top-Down Fabrication of ZnO Nanowires by Atomic Layer Deposition and Anisotropic Dry Etch Process M. Ebert, N.A.B. Ghazali, K.S. Kiang, M.R.R. de Planque and H.M.H. Chong, Univ. of Southampton, UK	11P-11-49 Formation of Multi-Stacked Ge Quantum Dot Utilizing Carbon-Mediated Template and Its Photoluminescence Property Y. Itoh 1,2, T. Kawashima 1 and K. Washio 1, 1 Tohoku Univ. and 2 JSPS Res., Japan	11P-11-50 Withdrawn Mobility and Channel Length Dependency in ZnO Thin Film Transistors A. Mohamed 1, H.M.H. Chong 2 and K. Kalna 1, 1 Swansea Univ. and 2 Univ. of Southampton, UK
11P-11-51 A Novel PMMA/NEB Bilayer Process for Sub-15 nm Gold Nanoslits by RIE Assisted Electron Beam Lithography X. Huang, J. Shao, C. Tsou, S. Zhang, B. Lu and Y. Chen, Fudan Univ., China	11P-11-52 Fabrication of Cu ₂ ZnSnS ₄ thin Films by Non-Vacuum Process Using Electro-Deposition and Sulfurization with Liquid CS ₂ Sulfur Source C.E. Wang 1, T. Shimizu 2, S. Tanaka 3, T. Terui 3 and S. Shingubara 2, 1 Changchun Univ. of Sci. and Technol., China, 2 Kansai Univ. and 3 NICT, Japan	11P-11-53 Adsorption Behavior of Nanoparticles on V-Groove for One-Dimensional Array T. Ban, M. Uenuma 2, S. Migita 3, I. Yamashita 2, Y. Uraoka 2 and S. Yamamoto 1, 1 Ryukoku Univ., 2 NAIST and 3 AIST, Japan	11P-11-54 Fully Bottom-up Process to Fabricate Non-Closepacked Nanopillar Arrays for Photonic Applications S. Suganuma, Y. Kaneko, K. Namura and M. Suzuki, Kyoto Univ., Japan
11P-11-55 Impact of Ar ⁺ Ion Irradiation on Nickelidation Reaction of Si Nanowire Covered with Oxide Film S. Asada 1, S. Hashimoto 1, X. Zhang 1, T. Xu 1, S. Oba 1, R. Yokogawa 2, M. Tomita 1,2,3, A. Ogura 2, T. Matsukawa 4 and T. Watanabe 1, 1 Waseda Univ., 2 Meiji Univ., 3 JSPS and 4 AIST, Japan	11P-11-56 Evaluation of Controlled Strain in Silicon Nanowire by UV Raman Spectroscopy R. Yokogawa 1, S. Hashimoto 2, S. Asada 2, M. Tomita 1,2,3, T. Watanabe 2 and A. Ogura 1, 1 Meiji Univ., 2 Waseda Univ. and 3 JSPS, Japan	11P-11-57 High Density Formation of Ta-Ta-Oxide Core-Shell Nanodots Y. Wang, D. Takeuchi, A. Ohta, M. Ikeda, K. Makihara and S. Miyazaki, Nagoya Univ., Japan	11P-11-110L Nanoscale Surface Structural Evolution in GaAs Digital Wet Etching with Sub-second Oxidation and Dissolution Process R. Kuroda, X. Yin, and S. Kasai, Hokkaido Univ., Japan
11P-11-111L Switching Properties of NiO Nanowire ReRAM T. Aono 1, K. Sugawa 1, T. Shimizu 2, S. Shingubara 2 and K. Takase 1, 1 Nihon Univ. and 2 Kansai Univ., Japan			

Inorganic Nanomaterials

Chairperson:

11P-11-58 Raman Spectroscopy of Hexagonal Boron Nitride I. Wasny 1, P. Kazmierczak 1, Z. Klusek 2 and A. Wyszomolek 1, 1 Univ. of Warsaw and 2 Univ. of Lodz, Poland	11P-11-59 Raman and Photoluminescence Mapping of Few-Layer MoS ₂ H. Rho 1, H. Kim 1 and S.M. Kim 2, 1 Chonbuk Natl. Univ. and 2 KIST, Korea	11P-11-60 Photoluminescence Characterization of Mono Layer MoS ₂ by Laser Thinning T. Minamino 1, T. Murakami 2, K. Kisoda 1 and C. Itoh 2, Wakayama Univ., Japan	11P-11-61 Engineering of Dielectric/Ferroelectric Responses in 2D Perovskites M. Osada, NIMS, Japan
11P-11-62 Formation of Crystalline Heteroepitaxial SiC Films on Si by Carbonization of Polyimide Langmuir-Blodgett Films V.V. Luchinin 1, S.I. Goloudina 1, V.M. Pasyuta 1, M.F. Panov 1, A.N. Smirnov 2, D.A. Kirilenko 2, T.F. Semenova 3, 1 St. Petersburg Electrotechnical Univ., 2 Loffe Inst. RAS and 3 St. Petersburg Univ., Russia	11P-11-63 Development of the Pulsed Laser Liquid Phase Epitaxy Process for High Quality SiC Films R. Yamaguchi 1, A. Onuma 1, A. Osumi 1, S. Maruyama 1, T. Mitani 2, T. Kato 2, H. Okumura 2 and Y. Matsumoto 1,3, 1 Tohoku Univ., 2 AIST and 3 JST-ALCA, Japan	11P-11-64 Surface Stress Relief During Ge Wetting Layer and Nanodot Formation on Si(111) Y. Uozumi 1,2, T. Yamazaki 3 and H. Asaoka 1, 1 JAEA, 2 Hitachi Power Solution and 3 Eiko Eng., Japan	11P-11-65 Characterization of ALON Buffer Layers for GaN Growth on Sapphire Substrate T. Hata 1, T. Yamazaki 1, Y. Yamane 1, K. Kumakura 2, H. Yamamoto 2 and T. Makimoto 1, 1 Waseda Univ. and 2 NTT, Japan

11P-11-66 Electronic Structure of Amorphous WO _{3-x} Thin Film by Soft-X-Ray Spectroscopy T. Sugimoto 1, W. Namiki 1, M. Ochi 1, T. Higuchi 1, T. Tsuchiya 2, M. Minohara 3, M. Kobayashi 3, K. Horiba 3, H. Kumigashira 3 and K. Terabe 2, 1 Tokyo Univ. of Sci., 2 NIMS and 3 KEK, Japan	11P-11-67 Optical Hydrogen Gas Sensor Consisting of Pd-Loaded Titania Nanocomposite Coating on Flexible Plastic Substrate J. Hamagami, G. Takaya and A. Endo, Kanto Gakuin Univ., Japan	11P-11-68 A High Performance Microbial Fuel Cell with Nickel Nanoparticle as Cathode Catalyst M. Gebresemati, W.G. Kidanu, S.W. Yoon and H.H. Yoon, Gachon Univ., Korea	11P-11-69 Synthesis of Ag ₃ VO ₄ Nanoparticles Loaded on Bi ₂ MoO ₆ Nanoplates as Heterostructured Visible Light Driven Photocatalyst A. Phuruangrat, Prince of Songkla Univ., Thailand
11P-11-70 Tuning the Single-molecule Conductance of Extended Metal-Atom Chains by Electrochemical Gating C.H. Chen E.-C. Horng, C.-H. Ho, T.-C. Ting, L.-Y. Hsu, M.-J. Huang, H.-C. Lu, C.-H. Hsu and S.-M. Peng, Natl. Taiwan Univ., Taiwan	11P-11-71 Effect of Starting Powder Morphology on Film Texture for Bismuth Layer-Structured Ferroelectrics Prepared by Aerosol Deposition Method M. Suzuki, T. Tsuchiya and J. Akedo, AIST, Japan		
Nanoimprint, Nanoprint and Rising Lithography			
Chairperson: M. Okada (Univ. of Hyogo)			
11P-11-72 Development of Multi-Layer Imprint Process for Solid Oxide Fuel Cell K. Tokumaru, F. Tsumori, K. Kudo, T. Osada and K. Shinagawa, Kyushu Univ., Japan	11P-11-73 Controllable Micro-Optical Element Molds Fabricated by Self-assembly Templating and Metal-Assisted Chemical Etching P. Jin, Y. Han, A. Jin and A. Wang, Harbin Inst. of Technol., China	11P-11-74 Implementation of a Nanoimprint First Level into Device Fabrication Flows Which Require High Alignment Accuracy S. Pauliac-Vaujour and S. Landis, CEA-LETI, France	11P-11-75 Large-Scale Patterning Diamond Nanopillar Arrays Using Metal Contact Nanoimprinting W. Zhang 1, Y. Wang 1,2, Y. Wu 1, B. Zhang 1, P. Jin 2, 1 Suzhou Inst. of Nano-Tech and Nanobionics and 2 Harbin Inst. of Technol., China
11P-11-76 High-Aspect-Ratio Structure Fabrication by Room-Temperature Nanoimprinting M. Okada and S. Matsui, Univ. of Hyogo, Japan	11P-11-77 Characteristic Evaluation of Organic Light-Emitting Diodes by Stamp Printing Technique A. Chittawanij and K. Locharoenrat, King Mongkut's Inst. of Technol., Thailand	11P-11-78 Dependence of Film Thickness on Surface Elasticity and Acrylate Consumption in UV-Cured Thin Film on Au Surfaces H. Yano 1, X. Liang 2, S. Kubo 3, N. Fukuda 4, H. Ushijima 4, K. Nakajima 2 and M. Nakagawa 1, 1 Tohoku Univ., 2 Tokyo Inst. of Technol., 3 NIMS and 4 AIST, Japan	
BioMEMS, Lab on a Chip			
Chairperson: T. Akagi (Univ. of Tokyo)			
11P-11-79 Numerical Investigation of Perforated Polymer Microcantilever Sensor for Contractile Behavior of Cardiomyocytes T.N. Nguyen, D.-W. Lee and B.-K. Lee, Chonnam Natl. Univ., Korea	11P-11-80 Optical Trapping Dynamics Depend on Initial Assembling of Quantum-Dotconjugated Glutamate Receptors on Hippocampal Neurons T. Kishimoto 1,2, Y. Maezawa 1, S.N. Kudoh 2, T. Taguchi 3 and C. Hosokawa 1,2, 1 AIST, 2 Kwansai Gakuin Univ. and 3 NICT, Japan	11P-11-81 Thermal Bonding of Polyimide to Form Sealing Microchannels H. Mearu, AIST, Japan	11P-11-82 Long-term Perfusion Culture Model of 3D Microvascular Remodeling S. Maeda 1, A. Takano 1, A. Nakamasu 2, R. Yokokawa 3, T. Miura 2 and N. Futai 2, 1 Shibaura Inst. of Technol., 2 Kyushu Univ. and 3 Kyoto Univ., Japan
11P-11-83 Development of Micro-Tube Mass Production Device for Microbial Culture in Open Environment K. Fujimoto, K. Higashi, H. Onoe and N. Miki, Keio Univ., Japan	11P-11-84 Reduction of Analysis Time in the Size Separation of Large DNA Using Size Exclusion Chromatography-Based Electrophoresis Microchip Driven by Pulsed Electric Field N. Azuma, S. Itoh, K. Fukuzawa and H. Zhang, Nagoya Univ., Japan	11P-11-85 Rapid and Sensitive Detection of Interleukin-6 with a Sandwich Immunoassay on the Plasmonic Chip K. Tawa 1, M. Sumiya 1, C. Sasakawa 1, T. Sujino 2, H. Nakazawa 2 and M. Umetsu 2, 1 Kwansai Gakuin Univ. and 2 Tohoku Univ., Japan	11P-11-86 Surface Stress Evaluation Induced by Biomolecular Adsorption on Freestanding Elastomer Nanosheet R. Teramoto 1, T. Fujie 2,3, N. Sato 4, S. Takeoka 4, K. Sawada 1 and K. Takahashi 1,3, 1 Toyohashi Univ. of Technol., 2 Waseda Univ. and 3 JST-PRESTO, Japan
11P-11-87 A Miniaturized Total Analysis System for Real-Time PCR H. Nagai 1, N. Naruishi 1, S. Furutani 1 and T. Fukuzawa 2, 1 AIST and 2 Nippon Sheet Glass, Japan	11P-11-112L Proposal of Molecular Tensile Testing by a Centrifugal Microfluidic Approach M. Otake and Y. Ukita, Univ. of Yamanashi, Japan	11P-11-113L Cell Migration Control by Boundary Shape of Topographical Structure C. Okutani, A. Wagatsuma, K. Mabuchi and T. Hoshino, Univ. of Tokyo, Japan	11P-11-114L Fabrication of Nanoarrays for Exosome Fixation by Lift-off Process and Chemical Modification in Aqueous Solution S. Yokota, H. Kuramachi and T. Ichiki, Univ. of Tokyo, Japan

Microsystem Technology and MEMS			
Chairperson: S. Nagasawa (Shibaura Inst. of Technol.)			
11P-11-88 Patterning of Wettability Using the Photocatalytic Decomposition of Hydrophobic SAM on the TiO ₂ Pattern H. Maeda, T. Kobayahi and S. Konishi, Ritumeikan Univ., Japan	11P-11-89 Possibility of Practical Application of Al/Ni Exothermic Reactive Bonding Technique for Hermetic Packaging K. Kuwabara 1, S. Ito 1, S. Kanetsuki 2,3, S. Miyake 4, S. Inoue 1 and T. Namazu 3, 1 Univ. of Hyogo, 2 Kobelco Res. Inst., 3 Aichi Inst. of Technol. and 4 Kobe City College of Technol., Japan	11P-11-90 Investigation of Aluminum/Nickel Multilayered Block Size for Self-Propagating Exothermic Reaction on a Silicon Wafer T. Namazu 1, S. Ito 2, S. Kanetsuki 1,3 and S. Miyake 4, 1 Aichi Inst. of Technol., 2 Univ. of Hyogo, 3 Kobelco Res. Inst. and 4 Kobe City College of Technol., Japan	11P-11-91 Development of Magnetic-Driven Artificial Cilia with High Aspect Ratio R. Marume, F. Tsumori, K. Kubo, T. Osada and K. Shinagawa, Kyushu Univ., Japan
11P-11-92 MEMS Origami Sheet without Vacuum Process S. Akashi and S. Nagasawa, Shibaura Inst. of Technol., Japan	11P-11-93 Fabrication of Microstructures on Dry-transferred Freestanding Graphene for Nanomechanical Resonator K. Go 1, H. Ishida 1, K. Sawada 1 and K. Takahashi 1,2, 1 Toyohashi Univ. of Technol. and 2 JST-PRESTO, Japan	11P-11-94 Micro Brush Actuator Using Self-Oscillating Gel T. Hirakawa and S. Maeda, Shibaura Inst. of Technol., Japan	11P-11-95 Raman Spectroscopic Study on Focused Ion Beam Induced Damage in Silicon Surface Y. Goshima 1, S. Kashiwagi 1, S. Inoue 2 and T. Namazu 3, 1 Horiba, 2 Univ. of Hyogo and 3 Aichi Inst. of Technol., Japan
11P-11-96 Long-Term Evaluation of Biofouling in Microfluidic Channels for Implantable Artificial Kidney T. Ota 1, N. To 1, Y. Kanno 2 and N. Miki 1, 1 Keio Univ. and 2 Tokyo Medical Univ., Japan	11P-11-97 Synthesis of Copper (I) Complex with Cu-C Bond for Photoluminescent Devices T. Hayakawa, Y. Yabara, M. Hashimoto, H. Teramae, H. Miyamae and T. Sakata, Josai Univ., Japan	11P-11-115L Spiking Neural Networks with Unsupervised Learning Based on STDP Using Resistive Synaptic Devices and Analog CMOS Neuron Circuit M.-W. Kwon, J. Park, M.-H. Baek, S. Hwang and B.-G. Park, Seoul Natl. Univ., Korea	11P-11-116L Microfabrication of Stretchable Electrocardiogram Device with a Flexible Skin Patch for Continuous Monitoring of Biological Signals W.I. Jang, B.K. Lee, J.H. Ryu, I.-B. Baek, S. Byun, H.Y. Yu and S. Kim, ETRI, Korea
11P-11-117L Development of Wireless, Chipless Neural Stimulator by Using One-Port SAW Delay Line and Diodecapacitor Interface J. Kim, S. Kim and K. Lee, Ajou Univ., Korea	11P-11-118L Spherically Deformable Convex Micromirror for Beam-Spot Imaging M.M. Hossain, J.Y. Lee and S.H. Kong, Kyungpook Natl. Univ., Korea	11P-11-119L Operation of Three-Dimensional MEMS Mirror by Single Superposed Driving Signal T. Nagasawa, Y. Oguchi and E. Iwase, Waseda Univ., Japan	